

Products Catalog

Fixed Resistors

- General purpose chip resistors type
- High precision type
- Current sensing type
- Small & High power type

- Anti-Sulfurated type
- High temperature type
- Array type / Resistor network



IN Your Future





Fixed Resistors (Surface Mount Resistors) INDEX

Classification	Product item	Part No.	Page
	Safety and Legal Matters to Be Observed / Matters to Be Observed	When Using This Product	1
General purpose	Thick film chip resistors	ERJ XG, 1G, 2G, 3G, 6G, ERJ 8G*, 14*, 12*, 12Z*, 1T*	5
chip resistors	Precision thick film chip resistors	ERJ XG, 1G, 1R, 2R, 3R, 6R, 3E, 6E, 8E*, ERJ 14*, 12*, 1T*	8
	Thin film chip resistors, High voltage type	ERA 8P	12
High	Thin film chip resistors, High stability and reliability type	ERA 2V, 3V, 3K, 6V, 6K, 8V, 8K	14
precision	Metal film (Thin film) Chip resistors, High reliability type	ERA 1A, 2A, 3A, 6A, 8A	17
	High precision thick film chip resistors	ERJ PB3, PB6	20
Current sensing	Thick film chip resistors / Low resistance type	ERJ 2LW, 3LW, 6LW, ERJ 2BW,3BW,6BW,8BW,6CW,8CW ERJ 2B, 3B, 6D, 6B, 8B, 14B, 3R, 6R, 8R, 14R, ERJ 12R, 12Z, ERJ 1TR, L03, L06, L08, L14, L12, L1D	22
Current sensing	Current sensing resistors, Metal plate type	ERJ MS4S, MS4H, MB1S	28
	High power chip resistors / Wide terminal type	ERJ A1, B1, B2, B3	32
	Low TCR high power chip resistors / Wide terminal type	ERJ D1, D2	37
	Anti-Surge thick film chip resistors	ERJ PA2, P03, PA3, P06, P08, PM8, P14	40
Small & High power	Anti-Surge thick film chip resistors (Double-sided resistive elements structure)	ERJ P6W*	45
	Anti-Pulse thick film chip resistors	ERJ T06, T08, T14	47
	Anti-Sulfurated thick film chip resistors	ERJ S02, S03, S06, S08, S14, S12, S1D, S1T, ERJ U0X, U01, U02, U03, U06, U08, U14, U12, ERJ U1D, ERJ U1T, ERJ U6S, U6Q	50
Anti-Sulfurated	Anti-Sulfurated thick film chip resistors / Precision type	ERJ U2R, U3R, U6R	54
	Anti-Sulfurated thick film chip resistors / Anti-Surge type	ERJ UP3, UP6, UP8	56
	Anti-Sulfurated thick film chip resistors / Wide terminal type	ERJ C1	59
High temperature	High temperature thick film chip resistors (Automotive Grade)	ERJ H2G, H2C, H2R, H3G, H3E, H3Q, H6G, HP6	62
	Chip resistor array	EXB 14V, 18V, 24V, 28V, N8V, 2HV, 34V, V4V, 38V, V8V, S8V	65
Resistor	Anti-Sulfurated chip resistor array	EXB U14, U18, U24, U28, U2H, U34, U38	69
network/Array	Chip resistor networks	EXB D, E, A, Q	72
	Chip attenuator	EXB 14AT, 24AT	76
	Packaging methods (Ta	aping)	78
Common	Recommended land pa	attern	83
specifications	Recommended soldering of	conditions	86
	Standard for resistance value and re	esistance tolerance	87



Safety and Legal Matters to Be Observed

Product specifications and applications

- Please be advised that this product and product specifications are subject to change without notice for improvement purposes. Therefore, please request and confirm the latest delivery specifications that explain the specifications in detail before the final design, or purchase or use of the product, regardless of the application. In addition, do not use this product in any way that deviates from the contents of the company's delivery specifications.
- Unless otherwise specified in this catalog or the delivery specifications, this product is intended for use in general electronic equipment (AV products, home appliances, commercial equipment, office equipment, information and communication equipment, etc.).

 When this product is used for the following special cases, please separately discuss the delivery specifications suited to each application with the company. These include applications requiring special quality and reliability, wherein their failures or malfunctions may directly threaten human life or cause harm to the human body (e.g.: space/aircraft equipment, transportation/traffic equipment, combustion equipment, medical equipment, disaster prevention/crime prevention equipment, safety equipment, etc.).

Safety design and product evaluation

- Please ensure safety through protection circuits, redundant circuits, etc., in the customer's system design so that a defect in our company's product will not endanger human life or cause other serious damage.
- This catalog shows the quality and performance of individual parts. The durability of parts varies depending on the usage environment and conditions. Therefore, please ensure to evaluate and confirm the state of each part after it has been mounted in your product in the actual operating environment before use.
 If you have any doubts about the safety of this product, then please notify us immediately, and be sure to conduct a technical review including the above protection circuits and redundant circuits at your company.

Laws / Regulations / Intellectual property

- The transportation of dangerous goods as designated by UN numbers, UN classifications, etc., does not apply to this product. In addition, when exporting products, product specifications, and technical information described in this catalog, please comply with the laws and regulations of the countries to which the products are exported, especially those concerning security export control.
- Each model of this product complies with the RoHS Directive (Restriction of the use of hazardous substances in electrical and electronic equipment) (2011/65/EU and (EU) 2015/863). The date of compliance with the RoHS Directive and REACH Regulation varies depending on the product model. Further, if you are using product models in stock and are not sure whether or not they comply with the RoHS Directive or REACH Regulation, please contact us by selecting "Sales Inquiry" from the inquiry form.
- During the manufacturing process of this product and any of its components and materials to be used, Panasonic does not intentionally use ozone-depleting substances stipulated in the Montreal Protocol and specific bromine-based flame retardants such as PBBs (Poly-Brominated Biphenyls) / PBDEs (Poly-Brominated Diphenyl Ethers). In addition, the materials used in this product are all listed as existing chemical substances based on the Act on the Regulation of Manufacture and Evaluation of Chemical Substances.
- With regard to the disposal of this product, please confirm the disposal method in each country and region where it is incorporated into your company's product and used.
- The technical information contained in this catalog is intended to show only typical operation and application circuit examples of this product. This catalog does not guarantee that such information does not infringe upon the intellectual property rights of Panasonic or any third party, nor imply that the license of such rights has been granted.

Panasonic Industry will assume no liability whatsoever if the use of our company's products deviates from the contents of this catalog or does not comply with the precautions. Please be advised of these restrictions.



Matters to Be Observed When Using This Product

(Fixed resistor)

Use environments and cleaning conditions

- This product (fixed resistor) is not designed for use in specific environments. Using the resistor in the following specific environments or service conditions may affect the performance/reliability of the resistor. Avoid using it in such specific environments. If you intend to use the resistor in such environments, checking the performance, reliability, etc., of the product sufficiently is your own responsibility.
 - (1) Used in liquid, such as water, oil, chemicals, and organic solvents.
 - (2) Used in a place exposed to direct sunlight, an outdoor place with no shielding, or a dusty place.
 - (3) Used in a place where the product is heavily exposed to sea breeze or a corrosive gas, such as Cl₂, H₂S, NH₃, SO₂, or NO_X.
 - (4) Used in an environment where static electricity and electromagnetic waves are strong.
 - (5) Located close to a heating component or a flammable material, such as a vinyl cable placed near the product.
 - (6) Sealed or coated with a resin.
 - (7) Solder flux of the resistor soldered with no-clean type solder, etc., is cleansed with a solvent, water, or a water-soluble cleaner, etc. (Water-soluble flux residues have a particularly large influence on a resistor.)
 - (8) Used in a place where dew concentrates on the product.
 - (9) Used in a contaminated state.

 (Example: Touching the resistor mounted on a printed board leaving sebum on the resistor (improper handling))
- Sealing the resistor with a resin in a resin potting process, damp-proofing process, etc., applies excessive stress to the resistor, which may cause the internal electrodes a connection problem. In such cases, the proper operation of the resistor is not guaranteed. If you intend to use the resistor in such environments, checking the performance, reliability, etc., of the product sufficiently is your own responsibility.
- Do not leave the resistor immersed in a solvent for a long time. When using the resistor immersed in a solvent, confirm the operation of the product mounted on the board.
- When a cleaning solution or cleaning condition for cleaning the printed board or a drying condition for drying the printed board after soldering the resistor is improper, it may have a negative effect on the performance/reliability of the resistor. Confirming these conditions sufficiently is your own responsibility. Also examine the effects of soiled cleaning agent, cleaning residues, and post-cleaning contaminations, and control for these effects properly.

Response to anomalies and handling conditions

- When the resistor is heating abnormally or emitting a smell, stop using the resistor immediately, for example, turn off the main power supply of the device.
 Also, keep your face and hands away from the product as it may become hot and cause burns.
- The resistor is so thin that it may break easily when subjected to impact. Before putting the resistor in use, confirm that the resistor has not been broken by impact that applied thereto when mounted on the printed board. Applying impact to the resistor or pinching the resistor with a hard tool (pliers, tweezers, etc.) may chip the resistor or its protective film, which affects its performance. Be careful to avoid such cases.
- Do not reuse a resistor having been used on a printed board and removed therefrom. Do not touch the resistor with your bare hands.
- Be careful not to drop the resistor on the floor, etc. The resistor is likely to suffer mechanical or electrical damage when dropped on the floor. Avoid using said resistor.
- The resistor may have its resistance value changed due to electrostatic discharge (ESD). Take ESD prevention measures when handling the resistor. ESD prevention measures include an environment where static electricity is not likely to be generated (recommended RH: 40% to 60%), by wearing an earth band, conductive gloves, etc., grounding the device in which the resistor is incorporated, and placing a conductive mat, etc., on a work platform.
- It is guaranteed that a resistor not exposed to any stress will have its proper resistance value. Any stress or pressure applied to the resistor may cause its resistance value to change. Examine and evaluate the characteristics of the resistor sufficiently before using it.



Reliability and product life

A capacitor conforming to "AEC-Q200" refers to a capacitor having passed some or all of evaluation test items defined in AEC-Q200.

To know the detailed specifications of each capacitor or specific evaluation test scores, please contact us. We issue a delivery specification sheet for each product ordered. Please confirm the delivery specification sheet when you place an order with us.

Circuit design and circuit board design

- To prevent a case where a transient load (e.g., a pulse for a short period) too large for the product to handle is applied, make sure to evaluate and confirm the operation of the product incorporated in your product. Applying power or voltage (current) larger than the rated power or rated voltage (current) to the resistor may impair its performance and reliability. Make sure to use the resistor with power or voltage (current) equal to or lower than the rated power or rated voltage (current). The product warranty does not cover usage where an excessively large load, such as a pulse current, is applied to the product.
- The resistor may have a high temperature even when used with power equal to or lower than the rated power. Be careful in such cases. Another factor to be considered are effects on the board, peripheral components, etc., and the effects of peripheral components on the resistor. Make sure to confirm first that the temperature of the resistor incorporated in your product is equal to or lower than the specified temperature, and then use the resistor.
- When the resistors are connected in series or parallel, loads applied respectively to the resistors may not be equal to each other. Check whether the loads are equal in the actual circuit in which the resistors are incorporated.
- When a resistor is used in a high-frequency circuit, the resistor may fail to offer the required characteristics. Check whether the resistor offers the required characteristics in the actual circuit in which the resistors are incorporated.
- Be careful that unusual stress caused by an excessive bend of the printed board is not applied to the resistor. Design the circuit structure such that the resistor is not close to a perforated line for board splitting or on a line with sizable holes bored on the board.
- When a different component is mounted on the board where the resistor has been soldered, be careful that the board does not bend excessively. If necessary, provide the board with backup pins (support pins) to keep it straight.
- Avoid manual board splitting. Use a jig, etc., to break the board so that it does not bend excessively when split apart.

Mounting conditions

- When the product is used under mounting conditions departing from mounting conditions specified in our specification sheet, the product may be exposed to unexpected stress to fail. Be careful to avoid such a case. When mounting the resistor on a printed board, set the resistor's front and back surfaces in the direction indicated by the tape. Make sure to evaluate and confirm the operation of the resistor incorporated in your product and determine whether the resistor is usable as a component of the product.
- Set soldering conditions for the resistor within the recommended soldering conditions specified by our company. Any time, soldering condition departing from the specified soldering condition, such as a high peak temperature or a long heating may impair the performance/reliability of the resistor. Note that the specified soldering conditions indicate conditions under which degradation of the resistor characteristics does not occur but do not indicate conditions under which stable soldering can be performed. Check and set individual conditions under which stable soldering can be performed.
- Heat the resistor in advance so that a difference between the soldering temperature and the temperature of the resistor surface is reduced to 100 °C or lower. When dipping the soldered resistor in a solvent, etc., to cool the resistor rapidly, ensure that the temperature difference between the resistor and the solvent is 100 °C or lower during the dipping.
- When soldering the resistor using a soldering iron, apply hot air, etc., to the resistor to heat it sufficiently in advance and then solder the resistor without bringing the soldering iron tip into contact with the product. If the temperature of the soldering iron tip is high, finish the soldering work quickly (within 3 seconds when the temperature of the soldering iron tip is 350 °C or lower). In the case of a fixed resistor with low resistance, the resistor may fail to offer the exactly intended resistance value because of the variation in the solder volume, etc. Make sure to confirm the resistance value of the resistor in the actual circuit configuration.



- Soldering the resistor with too much solder or too little solder results in the poor reliability of the solder connection of the resistor. Use the proper volume of solder in the soldering process. Sufficiently check for the volume of solder used.
- Soldering with high bond strength or special property solder may affect the quality of the resistor. Do not use such solder.
- Use rosin-based solder flux. When using highly active solder flux made mainly of halogen (chlorine, bromine, etc.), flux residues may affect the performance and reliability of the resistor. Check the effects of flux residues before using the solder flux. Do not use highly acidic flux, water-soluble flux, or flux containing fluoride ions. When solder flux sticks to the resistor after the soldering process, the activation energy of the flux may corrode the resistor and cause it to fail. Prevent solder flux from sticking to the resistor.

Storage conditions

Keeping the product in the following environments or conditions may lead to degradation of its performance, solderability, etc. Do not keep the product in the following environments.

- (1) Stored in a place where the product is heavily exposed to sea breeze or a corrosive gas, such as Cl₂, H₂S, NH₃, SO₂, or NO_x.
- (2) Stored in a place where the product is exposed to direct sunlight.
- (3) Stored in a place where a temperature condition of 5 °C to 35 °C and a relative humidity condition of 45% to 85% cannot be maintained
- (4) Kept in storage for more than one year from the delivery date (when the product is kept in conditions excluding any of the environments (1) to (3)).

Reference information

Guidelines

Before using the resistor, refer to the technical report issued by JEITA, EIAJ RCR-2121B "Safety Application Guide for Fixed Resistor for Use in Electronic Equipment" revised in February 2015.

INDUSTRY

Thick Film Chip Resistors

ERJ type

ERJ XG, 1G, 2G, 3G, 6G series

ERJ 8G, 14, 12, 12Z, 1T series





(Oct. 2021) Products marked as "NRFND" are not recommended for new design Target products: ERJ8G, 14, 12, 12Z, 1T series Please refer to the recommended alternatives with "Design Support Tool"

Features

Small size and lightweight

: Metal glaze thick film resistive element and three layers of electrodes High reliability

 Compatible with placement machines : Taping packaging available

Suitable for both reflow and flow soldering

 Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C

AEC-Q200 compliant (except ERJXG, ERJ1GN)

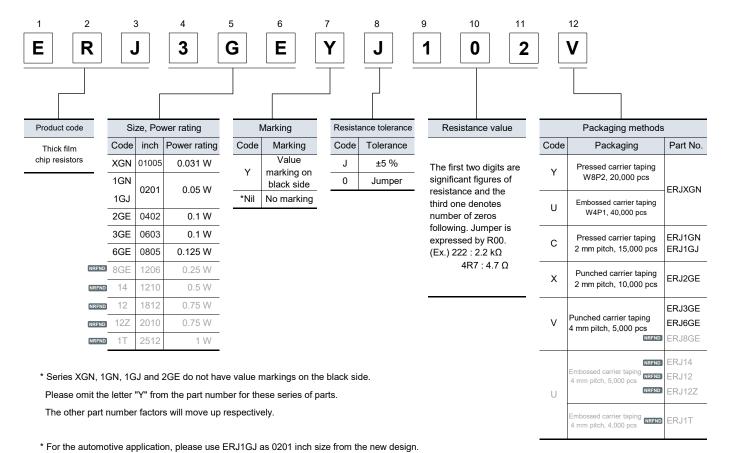
RoHS compliant

■ As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note: Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.

● ERJXGN, 1GN, 1GJ, 2GE, 3GE, 6GE, 8GE, 14, 12, 12Z, 1T series, ±5 %



Not recommended for new design

Ratings

[For Resistor]

Part No. (inch size)	Rated power ^{*1} (70 ℃) (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	Resist ran (Ω	ge	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJXG (01005)	0.031	15	30	±5	1 to 1 M	(E24)	R<10Ω : −100 to +600 10Ω to 100Ω : ±300 100Ω≤R : ±200		-
ERJ1GN (0201)	0.05	25	50	±5	1 to 10 M	(E24)		-55 to +125	
ERJ1GJ (0201)	0.05	25	50	±5	1 to 10 M	(E24)	R<10 Ω : –100 to +600		Grade 1
ERJ2G (0402)	0.1	50	100	±5	1 to 10 M	(E24)	10 Ω to 1 M Ω : ±200		
ERJ3G (0603)	0.1	75	150	±5	1 to 10 M	(E24)	1 MΩ <r +150<="" -400="" :="" td="" to=""><td>-55 to +155</td><td>Grade 0</td></r>	-55 to +155	Grade 0
ERJ6G (0805)	0.125	150	200	±5	1 to 10 M	(E24)			
ERJ8G (1206)	0.25	200	400	±5	1 to 10 M	(E24)			
ERJ14 (1210)	0.5	200	400	±5	1 to 10 M	(E24)	R<10 Ω : -100 to +600		
ERJ12 (1812)	0.75	200	500	±5	1 to 10 M	(E24)	10 Ω to 1 M Ω : ±200	-55 to +155	Grade 0
ERJ12Z (2010)	0.75	200	500	±5	1 to 10 M	(E24)	1 MΩ <r +150<="" -400="" :="" td="" to=""><td></td><td></td></r>		
ERJ1T (2512)	1	200	500	±5	1 to 1 M	(E24)			

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

[For Jumper]

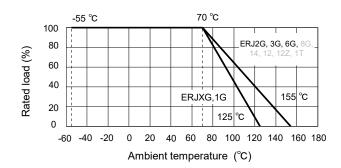
	Part No.	Resistance(Ω)	Rated current(A)	Maximum overload current (A) ^{*1}
	ERJXG		0.5	1
	ERJ1G		0.5	ı
	ERJ2G ERJ3G	$50~\text{m}\Omega$ or less	1	2
			ı	2
	ERJ6G		2	4
NR	ERJ8G			
NR	ERJ14			
NRI	ERJ12	$50~\text{m}\Omega$ or less	2	4
NR	ERJ12Z			
NR	ERJ1T			

^{* 1 :}Overload test current

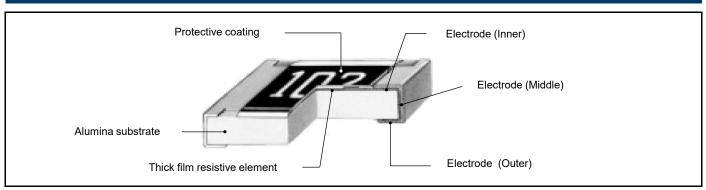
Not recommended for new design

Power derating curve

above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure below.



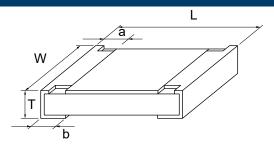
Construction



^{*2:} Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

^{*3:} Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Dimensions (not to scale)



Unit : mm

Part No.			Dimensions			Mass (Weight) (Reference)
raitino.	L	W	а	b	Т	(g/1000 pcs)
ERJXG	0.40±0.02	0.20±0.02	0.10±0.03	0.10±0.03	0.13±0.02	0.04
ERJ1G	0.60±0.03	0.30±0.03	0.10±0.05	0.15±0.05	0.23±0.03	0.15
ERJ2G	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8
ERJ3G	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2
ERJ6G	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4
NREND ERJ8G	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10
NREND ERJ14	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16
NRFND ERJ12	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27
NRFND ERJ12Z	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27
NRFND ERJ1T	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45

NRFND Not recomm

Not recommended for new design

Performance

Test item	Performance re	quirements ⊿R	Test conditions		
i est item	Resistor type	Jumper type	rest contaitions		
Resistance	Within specified tolerance	50 mΩ or less	20 ℃		
T. C. R.	Within specified T. C. R.	50 mΩ or less	+25℃ / +155℃ (ERJXG,1G : +25℃ / +125℃)		
Overload	±2 %	50 mΩ or less	Rated voltage× 2.5, 5 s Jumper type : Max. overload current, 5 s		
Resistance to soldering heat	±1 %	50 mΩ or less	270 °C, 10 s		
Rapid change of temperature	±1 %	50 mΩ or less	–55 °C (30 min.) / +155 °C (ERJXG,1G : +125 °C) (30 min.), 100 cycles		
High temperature exposure	±1 %	50 mΩ or less	+155℃ (ERJXG,1G : +125℃), 1000 h		
Damp heat, Steady state	±1 %	50 mΩ or less	60 ℃, 90 % to 95 %RH, 1000 h		
			60 ℃, 90 % to 95 %RH,		
Load life in humidity	±3 %	50 mΩ or less	Rated voltage (Jumper type :Rated current),		
			1.5 h ON / 0.5 h OFF cycle, 1000 h		
	±3 %	50 mΩ or less	70℃, Rated voltage (Jumper type : Rated current),		
Endurance at 70℃	±3 70	50 HILL OF IESS	1.5 h ON / 0.5 h OFF cycle, 1000 h		

Panasonic

INDUSTRY

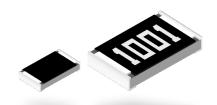
Precision Thick Film Chip Resistors

ERJ type

ERJ XG, 1G series

ERJ 1R, 2R, 3R, 6R series

ERJ 3E, 6E, 8E, 14, 12, 1T series





(Oct. 2021) Products marked as "NRFND" are not recommended for new design. Target products: ERJ8E, 14, 12, 1Tseries Please refer to the recommended alternatives with "Design Support Tool".

Features

Small size and lightweight

High reliability : Metal glaze thick film resistive element and three layers of electrodes

● Compatible with placement machines : Taping packaging available

Suitable for both reflow and flow soldering

● Low resistance tolerance : ERJXG, 1G, 2R, 3E, 6E, 8E, 14, 12, 1T series : ±1 %

ERJ1R, 2R, 3R, 6R series : ±0.5 %

■ Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C

AEC-Q200 compliant (except ERJ1R, ERJXG, ERJ1GN)

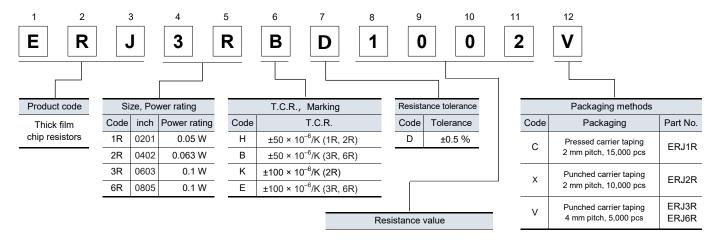
RoHS compliant

■ As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note: Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.

ERJ1R, 2R, 3R, 6R series : ±0.5 %



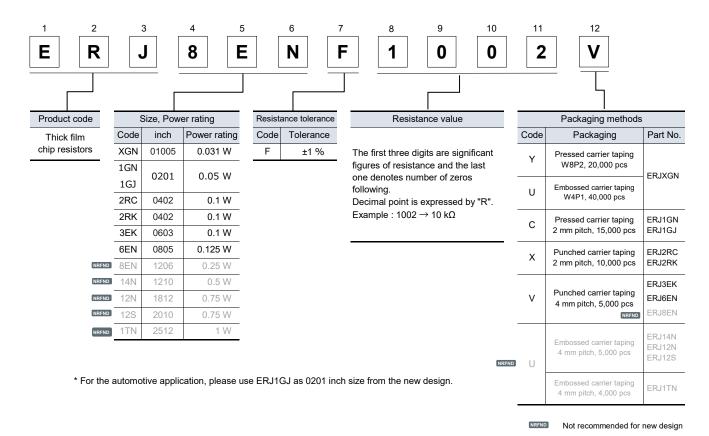
The first three digits are significant figures of resistance and the last one denotes number of zeros following.

Example : $1002 \rightarrow 10 \text{ K}\Omega$

Explanation of part numbers

Note: Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.

ERJXGN, 1GN, 1GJ, 2RC, 2RK, 3EK, 6EN, 8EN, 14N, 12N, 12S, 1TN series: ±1 %



Ratings

<±0.5 %>

\±0.0 /(C10.3 707										
Part No. (inch size)	Rated power ^{*1} (70 °C) (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	Resistance range (Ω)		range		T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJ1RH (0201)	0.05	15	30	±0.5	1 k to 1 M	(E24,E96)	±50	-55 to +125	-		
ERJ2RH (0402)	0.063	50	100	±0.5	100 to 100 k	(E24,E96)	±50				
ERJ2RK (0402)	0.063	50	100	±0.5	10 to 97.6 102 k to 1 M	(E24,E96)	±100				
ERJ3RB (0603)	0.1	75	150	±0.5	100 to 100 k	(E24,E96)	±50	-55 to +155	Grade 0		
ERJ3RE (0603)	0.1	75	150	±0.5	10 to 97.6 102 k to 1 M	(E24,E96)	±100	-55 10 + 155	Grade 0		
ERJ6RB (0805)	0.1	150	200	±0.5	100 to 100 k	(E24,E96)	±50				
ERJ6RE (0805)	0.1	150	200	±0.5	10 to 97.6 102 k to 1 M	(E24,E96)	±100				

^{*1 :} Use it on the condition that the case temperature is below the upper category temperature.

^{*2 :} Rated continuous working voltage (RCWV) shall be determined from RCWV=√Power rating × Resistance value, or limiting element voltage listed above, whichever less.

^{*3 :} Overload test voltage (OTV) shall be determined from OTV = specified magnification (refer to performance) × RCWV or maximum overload voltage listed above, whichever less.

Ratings

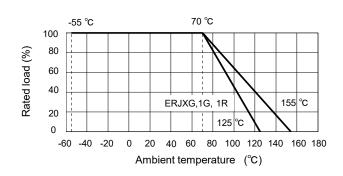
<±1 %>

Part No. (inch size)	Power rating ^{*1} (70 °C) (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	rar	Resistance T.C.R. range (Ω)		Category temperature range (°C)	AEC-Q200 Grade
ERJXGN (01005)	0.031	15	30	±1	10 to 1 M*4	(E24,E96)	R < 100 Ω : ±300 100 Ω ≤ R : ±200		
ERJ1GN (0201)	0.05	25	50	±1	10 to 1 M ^{*4}	(E24,E96)	±200	-55 to +125	
ERJ1GJ (0201)	0.05	25	50	±1	10 to 1 M*4	(E24,E96)	1200		Grade 1
ERJ2RC (0402)	0.1	50	100	±1	1 to 9.76	(E24,E96)	-100 to +600		
ERJ2RK (0402)	0.1	50	100	±1	10 to 1 M	(E24,E96)		-55 to +155	Grade 0
ERJ3EK (0603)	0.1	75	150	±1	10 to 1 M	(E24,E96)	±100		
ERJ6EN (0805)	0.125	150	200	±1	10 to 2.2 M	(E24,E96)			
ERJ8EN (1206)	0.25	200	400	±1	10 to 2.2 M	(E24,E96)			
ERJ14N (1210)	0.5	200	400	±1	10 to 1 M	(E24,E96)			
ERJ12N (1812)	0.75	200	500	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ12S (2010)	0.75	200	500	±1	10 to 1 M	(E24,E96)			
ERJ1TN (2512)	1	200	500	±1	10 to 1 M	(E24,E96)			

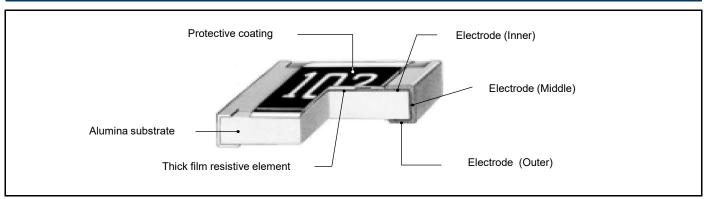
- *1 : Use it on the condition that the case temperature is below the upper category temperature.
- *2 : Rated continuous working voltage (RCWV) shall be determined from RCWV=√Power rating × Resistance value, or limiting element voltage listed above, whichever less.
- *3 : Overload test voltage (OTV) shall be determined from OTV = specified magnification (refer to performance) × RCWV or maximum overload voltage listed above, whichever less.
- *4 : Please contact us when you need a type with a resistance of less than 10 Ω .

Power derating curve

For resistors operated in ambient temperatures above 70 ℃, power rating shall be derated in accordance with the figure on the right.

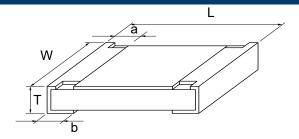


Construction



Not recommended for new design

Dimensions (not to scale)



Part No.			Dimensions (mm)			Mass (Weight)	
Fait No.	L	W	а	b	Т	(Reference) (g/1000 pcs)	
ERJXG	0.40±0.02	0.20±0.02	0.10±0.03	0.10±0.03	0.13±0.02	0.04	
ERJ1G	0.60±0.03	0.30±0.03	0.10±0.05	0.15±0.05	0.23±0.03	0.15	
ERJ1R	0.0010.03	0.3010.03	0.10±0.00	0.10±0.00	0.2310.03	0.10	
ERJ2R	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	8.0	
ERJ3R	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2	
ERJ3E	1.00±0.10	0.0010.13/-0.03	0.30±0.20	0.30±0.13	0.40±0.10	_	
ERJ6R	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4	
ERJ6E	2.00±0.20	1.20±0.10	0.4010.20	0.40±0.20	0.00±0.10		
NRFND ERJ8EN	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10	
NRFND ERJ14N	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16	
NRFND ERJ12N	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27	
NRFND ERJ12S	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27	
NRFND ERJ1TN	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45	

Not recommended for new design

Performance

● ERJ1R, 2R, 3R, 6R series: ±0.5 % (D)

Test item	Performance	Test conditions				
	requirements ⊿R					
Resistance	Within specified	20 ℃				
Nesistance	tolerance	20 C				
T. C. R.	Within specified	+25 ℃ / +125 ℃				
1. C. K.	T. C. R.	+25 C7 +125 C				
Overload ±2 %		Rated voltage × 2.5, 5 s				
Resistance to soldering heat	±1 %	270 ℃, 10 s				
Rapid change of temperature	±1 %	-55 °C (30 min.) / +155 °C (ERJ1R : +125 °C)(30 min.),				
Napid change of temperature	±1 /0	100 cycles				
High temperature exposure	±1 %	+155 ℃ (ERJ1R : +125 ℃), 1000 h				
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h				
Load life in humidity	±2 %	60 ℃, 90 % to 95 %RH, Rated voltage,				
Load life in humidity	ERJ1R: ±3 %	1.5 h ON / 0.5 h OFF cycle, 1000 h				
Endurance at 70 ℃	±2 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h				
	ERJ1R : ±3 %					

● ERJXGN, 1GN, 1GJ, 2RC, 2RK, 3EK, 6EN, 8EN, 14N, 12N, 12S, 1TN series: ±1 % (F)

Test item	Performance requirements ⊿R	Test conditions		
Resistance	Within specified tolerance	20 ℃		
T. C. R. Within specified T. C. R.		+25 °C / +155 °C (ERJXG,ERJ1G : +25 °C / +125 °C)		
Overload ±2 %		Rated voltage × 2.5, 5 s		
Resistance to soldering heat	±1 %	270 ℃, 10 s		
Rapid change of temperature	±1 %	–55 ℃ (30 min.)/+155 ℃ (ERJXG,ERJ1G : +125 ℃)(30 min.), 100 cycles		
High temperature exposure	±1 %	+155 ℃ (ERJXG,ERJ1G : +125 ℃), 1000 h		
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h		
Load life in humidity	±2 % ERJXG,1G : ±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		
Endurance at 70 ℃	±2 % ERJXG,1G : ±3 %	70 °C, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		

Panasonic

INDUSTRY

Thin Film Chip Resistors, High Voltage Type

ERA P type

ERA 8P series



Features

High voltage : Achieves high limiting element voltage with original design concept (500V @1MΩ)

High reliability : Stable at high temperature and humidity

(85 °C 85 %RH rated load, Category temperature range : –55 °C to +155 °C)

High accuracy : Low resistance tolerance and temperature coefficient of resistance

High performance : Low current noise, excellent linearity

• Anti-ESD : Original structure for high ESD performance

(AEC-Q200-002 HBM Guarantee at 4 kV)

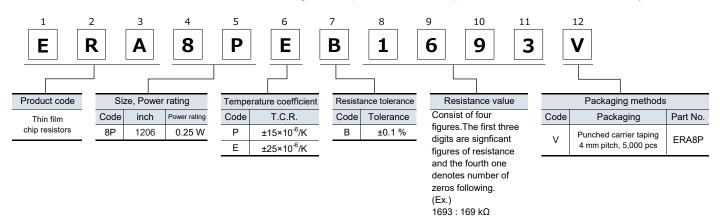
Anti-sulfurated : Original structure for sulfurated performance
 Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2133C

RoHS compliant

■ As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note: Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



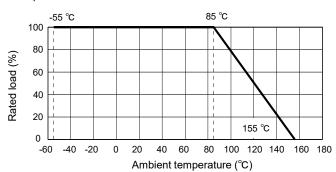
Ratings

Part No. (inch size)	Power rating at 85 ℃ ^{*1} (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage (V)	Part No. (detail)	Resistance tolerance (%)	T.C.R. (×10 ⁻⁶ /K)	Resistanc (Ω	· ·	Category temperature range (°C)	AEC-Q200 Grade
ERA8P	0.25	500	1000	ERA8PEB	±0.1	±25	160 k to 1 M	(E24, E96)	-55 to +155	Grade 0
(1206)	0.25	500 1000		ERA8PPB	10.1	±15	TOURIOTIVI	(624, 690)	-55 10 + 155	Grade 0

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

Power derating curve

For resistors operated in ambient temperatures above 85°C, power rating shall be derated in accordance with the figure on the right.

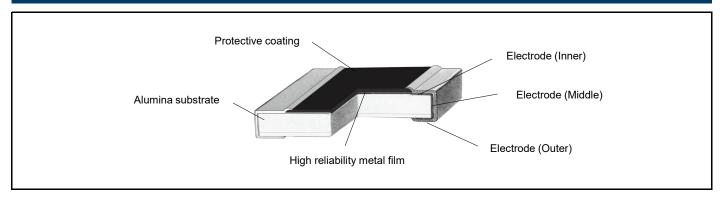


^{*2:} Rated continuous working voltage (RCWV) shall be determined from RCWV=√(Power Rating × Resistance Values), or limiting element voltage listed above, whichever less.

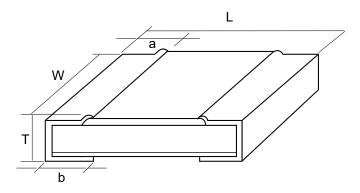
^{*3:} E192 series resistance values are also available. The E192 series has custom part numbers. Please contact us for details.

Thin Film Chip Resistors, High Voltage Type

Construction



Dimensions (not to scale)



Unit : mm

Part No.		Dimensions								
Part No.	L	W	а	b	Т	(Reference) (g/1000 pcs)				
ERA8P	3.20±0.20	1.60±0.10	0.50±0.20	0.50±0.20	0.55±0.10	10				

Performance

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 °C / +125 °C
Overload	±0.1 %	Specified magnification (2.5) × RCWV or Maximum overload voltage, whichever less, 5 s
Resistance to soldering heat	±0.1 %	270 ℃, 10 s
Rapid change of temperature	±0.1 %	-55 $^{\circ}$ C (30 min.) / +155 $^{\circ}$ C (30 min.), 1000 cycles
High temperature exposure	±0.1 %	+155 ℃, 1000 h
Damp heat, Steady state	±0.1 %	85 ℃, 85 %RH, 1000 h
Load life in humidity	±0.1 %	85 ℃, 85 %RH, 10 % of Rated power ^{*1} , 1.5 h ON / 0.5 h OFF cycle , 1000 h
Endurance at 85℃	±0.1 %	85 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Electro static discharge (HBM)	±0.1 %	AEC-Q200-002 : 150 pF, 2000 Ω, positive 5 times, negative 5 times
		ERA8P : 4.0 kV (Class 3)

^{*1:} Applied Voltage is " $\sqrt{0.1 \times \text{Power Rating} \times \text{Resistance Values}}$ ".

INDUSTRY

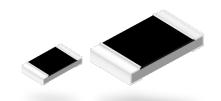
Thin Film Chip Resistors, **High Stability and Reliability Type**

ERA V type

(High resistance value ERA K type)

ERA 2V, 3V, 6V, 8V series

(ERA 3K, 6K, 8K series)



Features

: To realize higher power rating, Limiting element voltage, and maximum High Power

overload voltage than current products

: Stable at high temperature and humidity High reliability

(85 °C 85 %RH rated load, Category temperature range : -55 °C to +155 °C)

 High accuracy : Low resistance tolerance and temperature coefficient of resistance

 High performance : Low current noise, excellent linearity

Anti-ESD : Original structure for high ESD performance

(AEC-Q200-002 HBM Class 1c and above)

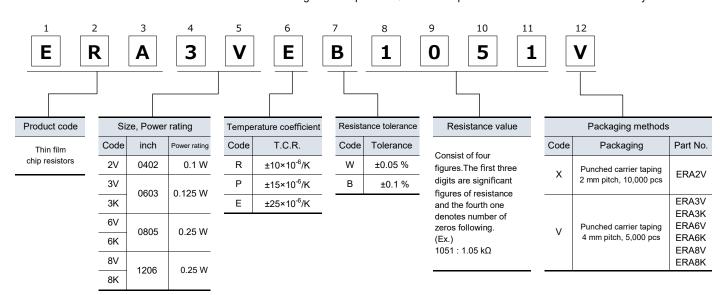
 Anti-sulfurated : Original structure for sulfurated performance : IEC 60115-8, JIS C 5201-8, JEITA RC-2133C Reference standard

RoHS compliant

■ As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note: Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



Thin Film Chip Resistors, High Stability and Reliability Type

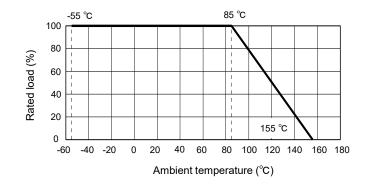
Ratings

Part No. (inch size)	Power rating at 85 ℃*1 (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Part No. (detail)	Resistance tolerance (%)	T.C.R. (×10 ⁻⁶ /K)	Resistance range ^{*4} (Ω)	Category temperature range (°C)	AEC-Q200 Grade
				ERA2VEB	±0.1	±25	47 to 100 k ^{*5} (E24, E96)		
ERA2V	0.1	75	150	ERA2VPB	±0.1	±15			
(0402)	0.1	75	150	ERA2VRB	±0.1	±10	1 k to 47 k *5 (E24, E96)		
				ERA2VRW	±0.05	±10			
				ERA3VEB	±0.1	±25	47 to 100 k (E24, E96)		
ERA3V	0.125	100	200	ERA3VPB	±0.1	±15			
(0603)	0.125	100	200	ERA3VRB	±0.1	±10	1 k to 100 k (E24, E96)		
				ERA3VRW	±0.05	±10			
ERA3K (0603)	0.125	100	200	ERA3KEB	±0.1	±25	102 k to 240 k (E24, E96)		
				ERA6VEB	±0.1	±25	47 to 100 k (E24, E96)		
ERA6V	0.25	450	150 300	ERA6VPB	±0.1	±15		-55 to +155	Grade 0
(0805)	0.25	150		ERA6VRB	±0.1	±10	1 k to 100 k (E24, E96)	-55 10 +155	Grade 0
				ERA6VRW	±0.05	±10			
ERA6K (0805)	0.25	150	300	ERA6KEB	±0.1	±25	102 k to 750 k (E24, E96)		
				ERA8VEB		±25	47 to 100 k (E24, E96)		
ERA8V	0.25	200	400	ERA8VPB	±0.1	±15	1 k to 100 k (E24, E96)		
(1206)	0.25	200	400	ERA8VRB		±10	1 k to 100 k (E24, E96)		
				ERA8VRW	±0.05	±10	1 K to 100 K (E24, E96)		
	ERA8K (1206) 0.25 200		ERA8KEB		±25	102 k to 1 M (E24 E06)			
ERA8K		200	400	ERA8KPB	±0.1	±15	102 k to 1 M (E24, E96)	_	
(1206)		200		ERA8KRB		±10	102 k to 160 k (E24, E96)		
				ERA8KRW	±0.05	110	102 K to 100 K (L24, E90)		

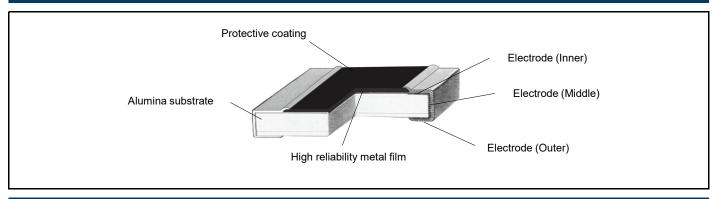
^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

Power derating curve

For resistors operated in ambient temperatures above 85°C, power rating shall be derated in accordance with the figure on the right.



Construction



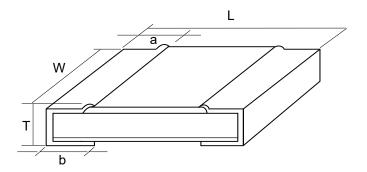
^{*2:} Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.

^{*3:} Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (2.5) × RCWV or Maximum Overload Voltage listed above, whichever less.

^{*4:} E192 series resistance values are also available. The E192 series has custom part numbers. Please contact us for details.

^{*5:} Expanded resistance range

Dimensions (not to scale)



Unit : mm

Part No.	Dimensions								
Fait No.	L	W	а	b	Т	(Reference) (g/1000 pcs)			
ERA2V	1.00±0.05	0.50+0.10/-0.05	0.25±0.10	0.25±0.10	0.35±0.05	0.6			
ERA3V,3K	1.60±0.15	0.80±0.10	0.30±0.20	0.30±0.20	0.45±0.10	2			
ERA6V,6K	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.55±0.10	5			
ERA8V,8K	3.20±0.20	1.60±0.10	0.50±0.20	0.50±0.20	0.55±0.10	10			

Performance

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload	±0.1 %	Rated voltage× 2.5, 5 s
Resistance to soldering heat	±0.1 %	270 ℃, 10 s
Rapid change of temperature	±0.1 %	-55 °C (30 min.) / +155 °C (30 min.), 1000 cycles
High temperature exposure	±0.1 %	+155 ℃, 1000 h
Damp heat, Steady state	±0.1 %	85 ℃, 85 %RH, 1000 h
Load life in humidity	±0.1 %	85 ℃, 85 %RH, 10 % of Rated power ^{*1} , 1.5 h ON / 0.5 h OFF cycle , 1000 h
Endurance at 85℃	±0.1 %	85 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
		AEC-Q200-002 : 150 pF, 2000 Ω, positive 5 times, negative 5 times
Electro static	±0.1 % ^{*2}	ERA2V : 1.0 kV (Class 1c)
discharge (HBM)	±0.1 % ⁻	ERA3V(3K) : 1.5 kV (Class 1c)
		ERA6V(6K) : 2.0 kV (Class 2)
		ERA8V(8K) : 2.0 kV (Class 2)

^{*1:} Applied Voltage is "√0.1 × Power Rating × Resistance Values", or "Limiting Element Voltage×0.316", whichever less.

^{*2:} Depends on resistance value.

Panasonic

INDUSTRY

Metal Film (Thin Film) Chip Resistors, High Reliability Type

ERA A type

ERA 1A, 2A, 3A, 6A, 8A series



Features

High reliability : Stable at high temperature and humidity

(85 °C 85 %RH rated load, Category temperature range : –55 °C to +155 °C)

• High accuracy : Low resistance tolerance and Temperature Coefficient of Resistance

High performance : Low current noise, excellent linearity

• Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2133C

AEC-Q200 compliant (except ERA1A)

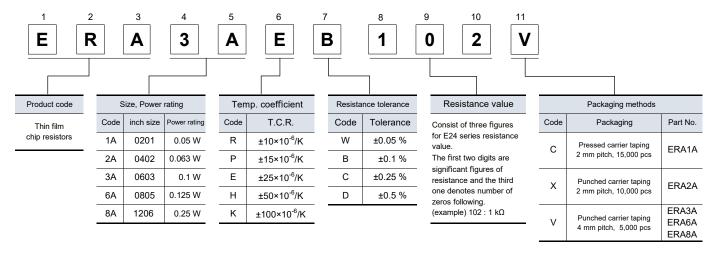
RoHS compliant

■ As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

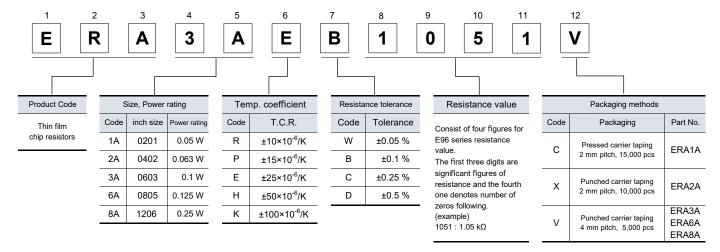
Explanation of part numbers

Note: Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.

E24 series



E96 series and other Resistance values



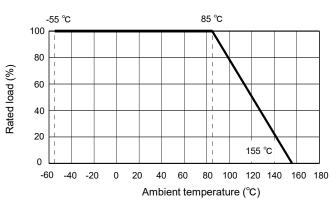
Note: Duplicated resistance values as E24 series part umbers shall follow E24 part numbers. (apply three digit resistance value)

Metal Film (Thin Film) Chip Resistors, High Reliability Type

Ratings Power Limiting Maximum Category Resistance Resistance element overload Part No. T.C.R. AEC-Q200 Part No. rating temperature range*4 *5 tolerance (inch size) voltage*2 voltage*3 (detail) range Grade (85 ℃) (×10⁻⁶/K) (%) (Ω) (\mathcal{C}) (W) (V) (V) **ERA1AEB** ±0.1 ±25 100 to 10 k (E24,E96) ERA1AEC ±0.25 ERA1A ±0.25 0.05 25 50 **ERA1ARC** (0201)(E24,E96) 100 to 10 k **ERA1ARB** ±0.1 ±10 1 k to 10 k (E24,E96) **ERA1ARW** ±0.05 ERA2AKD ±0.5 (E24,E96) ±100 10 to 46.4 ERA2AED ±0.5 **ERA2AEC** ±0.25 ±25 47 to 100 k (E24,E96) ERA2A ERA2AEB ±0.1 0.063 100 Grade 1 50 (0402)ERA2APC ±0.25 200 to 47 k ±15 (E24,E96) FRA2APB ±0.1 ERA2ARC ±0.25 ±10 200 to 47 k (E24.E96) **ERA2ARB** ±0.1 ERA3AHD 10 to 46.4 (E24,E96) ±0.5 ±50 **ERA3AED** ±0.5 ERA3AEC ±0.25 ±25 47 to 330 k (E24,E96) ERA3AEB ±0.1 ERA3A ±0.25 0.1 75 150 ERA3APC (0603)470 to 100 k (E24,E96) ±15 **ERA3APB** ±0.1 **ERA3ARC** ±0.25 -55 to +155 **ERA3ARB** 1 k to 100 k (E24,E96) ±0.1 ±10 **ERA3ARW** ±0.05 ERA6AHD (E24,E96) ±0.5 ±50 10 to 46.4 ERA6AED ±0.5 ERA6AEC ±0.25 47 to 1 M +25 (E24.E96) ERA6AEB ±0.1 ERA6A 0.125 100 200 ERA6APC ±0.25 Grade 0 (0805)470 to 100 k ±15 (E24,E96) **ERA6APB** ±0.1 **ERA6ARC** ±0.25 **ERA6ARB** 1 k to 100 k ±0.1 ±10 (E24,E96) **ERA6ARW** ±0.05 ERA8AHD ±0.5 (E24,E96) 10 to 46.4 ±50 ERA8AED ±0.5 ERA8AEC ±0.25 ±25 47 to 1 M (E24,E96) **ERA8AEB** ±0.1 ERA8A 0.25 150 300 FRA8APC ±0.25 (1206)470 to 100 k ±15 (E24,E96) **ERA8APB** ±0.1 ERA8ARC ±0.25 ERA8ARB ±0.1 ±10 1 k to 100 k (E24,E96) ERA8ARW ±0.05

Power derating curve

For resistors operated in ambient temperatures above 85 °C, power rating shall be derated in accordance with the figure on the right.



^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

^{*2:} Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.

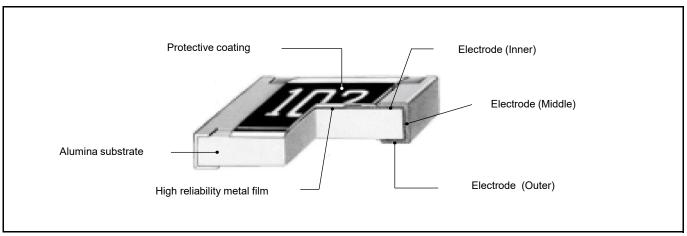
^{*3:} Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (2.5) × RCWV or Maximum Overload Voltage listed above, whichever less.

^{*4:} E192 series resistance values are also available. Please contact us for details.

^{*5:} Duplicated resistance values between E96, E192 and E24 series shall follow E24 Part Numbers. (apply three digit resistance value)

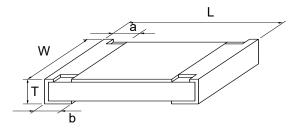
Metal Film (Thin Film) Chip Resistors, High Reliability Type

Construction



^{*0201/0402} size or E96 series do not have value markings.

Dimensions (not to scale)



Unit : mm

Part No.	Dimensions								
Tarrito.	L	W	а	b	Т	(Reference) (g/1000 pcs)			
ERA1A	0.60±0.03	0.30±0.03	0.15±0.05	0.15±0.05	0.23±0.03	0.14			
ERA2A	1.00±0.10	0.50+0.10/-0.05	0.15±0.10	0.25±0.10	0.35±0.05	0.6			
ERA3A	1.60±0.20	0.80±0.20	0.30±0.20	0.30±0.20	0.45±0.10	2			
ERA6A	2.00±0.20	1.25±0.10	0.40±0.25	0.40±0.25	0.50±0.10	4			
ERA8A	3.20±0.20	1.60+0.05/-0.15	0.50±0.25	0.50±0.25	0.60±0.10	8			

Performance

·		
Test Item	Performance	Test conditions
i est itemi	requirements ⊿R	i est conditions
Resistance	Within specified	20 ℃
Resistance	tolerance	20 C
T. C. R.	Within specified	+25 ℃ / +125 ℃
1. U. K.	T. C. R.	+25 C/+125 C
Overload	R<47 Ω: ±0.5 %	Datad voltage v 2.5.5 c
Overload	R≧47Ω : ±0.1 %	Rated voltage x 2.5, 5 s
Resistance to	R<47 Ω: ±0.5 %	270 ℃, 10 s
soldering heat	R≧47Ω : ±0.1 %	270 C, 10 S
Rapid change	R<47 Ω: ±0.5 %	ERA1A, 2A: -55 ℃ (30 min.) / +125 ℃ (30 min.),1000 cycles
of temperature	R≧47Ω : ±0.1 %	ERA3A, 6A, 8A : –55 ℃ (30 min.) / +155 ℃ (30 min.),1000 cycles
High temperature	R<47 Ω: ±0.5 %	+155 ℃, 1000 h
exposure	R≧47Ω : ±0.1 %	+155 C, 1000 H
Damp heat,	R<47 Ω: ±0.5 %	85 ℃, 85 %RH, 1000 h
Steady state	R≧47Ω : ±0.1 %	03 C, 03 70KH, 1000 H
Load life in	R<47 Ω : ±0.5 %	85 ℃, 85%RH, 10% rated power, 1.5 h ON / 0.5 h OFF cycle, 1000 h,
humidity	R≥47Ω:±0.1 %	Max. test voltage : ERA2A : 15.8 V, ERA3A : 23.7 V, ERA6A : 31.6 V,
Hamilalty	1\=\71\22\.\1\0\.\1\70	ERA8A : 47.4 V
Endurance at 85℃	R<47 Ω : ±0.5 %	95°C Detect violage 4.5 h ON / 0.5 h OFF evals 4000 h
Endurance at 65 C	R≧47Ω : ±0.1 %	85°C, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

Panasonic

INDUSTRY

High Precision Thick Film Chip Resistors

ERJ PB type

ERJ PB3, PB6 series



Features

• Achieve the resistance tolerance ±0.1 % with high reliability metal glaze thick film resistor

• Guarantee the temperature coefficient of Resistance ±50×10⁻⁶/K in high resistance range up to 1 MΩ

High power : 0.20 W : 0603 inch /1608 mm size(ERJPB3)

: 0.25 W: 0805 inch /2012 mm size(ERJPB6)

• Reference Standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C

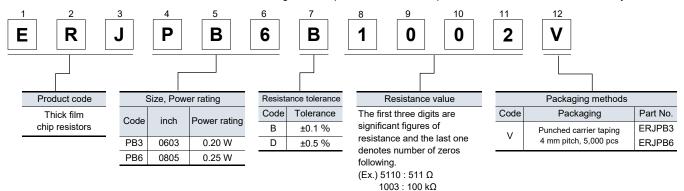
AEC-Q200 compliant

RoHS compliant

■ As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note: Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



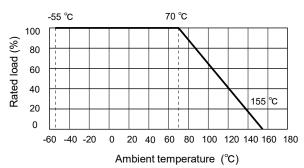
Ratings

Part No. (inch size)	Power rating ^{*1} (70 ℃)(W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (°C)	AEC-Q200 Grade
ERJPB3 (0603)	0.20	150	200	±0.1 ±0.5	200 to 100 k (E24, E96)	±50	-55 to +155	Grade 0
ERJPB6 (0805)	0.25	150	200	±0.1 ±0.5	200 to 1 M (E24, E96)	±50	-55 10 +155	Grade 0

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

Power derating curve

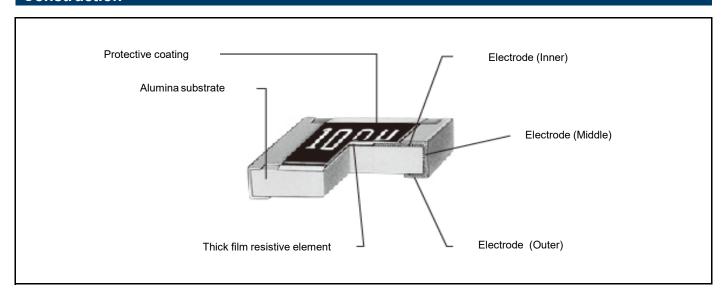
For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



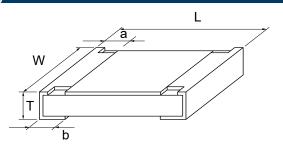
^{*2:} Rated continuous working voltage (RCWV) shall be determined from RCWV=√Power rating × Resistance value, or Limiting Element Voltage listed above, whichever less.

^{*3:} Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum overload voltage listed above, whichever less.

Construction



Dimensions (not to scale)



Unit : mm

Part No.	Dimensions								
raitino.	L	W	а	b	Т	(Reference) (g/1000 pcs)			
ERJPB3	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.25±0.10	0.45±0.10	2			
ERJPB6	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4			

Performance

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload	±0.5 %	Rated voltage× 2.0, 5 s
Resistance to soldering heat	±0.5 %	270 ℃, 10 s
Rapid change of temperature	±0.5 %	-55 °C (30 min.) / +155 °C (30 min.), 100 cycles
High temperature exposure	±0.5 %	+155 ℃, 1000 h
Damp heat, Steady state	±0.5 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±0.5 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±0.5 %	70 ℃, Rated voltage , 1.5 h ON / 0.5 h OFF cycle, 1000 h

Panasonic

INDUSTRY

Thick Film Chip Resistors (Low Resistance Type)

ERJ type

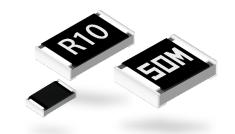
ERJ 2LW, 3LW, 6LW series

ERJ 2BW, 3BW, 6BW, 8BW, 6CW, 8CW series

ERJ 2B, 3B, 6D, 6B, 8B, 14B series

ERJ 3R, 6R, 8R, 14R, 12R, 12Z, 1TR series

ERJ L03, L06, L08, L14, L12, L1D series



Features

- Current sensing resistor
- Small size and lightweight
- Realize both low-resistance & High-precision by original thick film resistive element & special electrode structure
- Suitable for both reflow and flow soldering
- Realize High-power by double-sided resistive elements structure that aimed to suppress temperature rising

: ERJ2LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW

● Low TCR : ±75×10⁻⁶/K(ERJ6CW, ERJ8CW)

Low resistance value : Thick film resistors available from 5 mΩ (ERJ3LW, 6LW)

Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2144

AEC-Q200 compliant

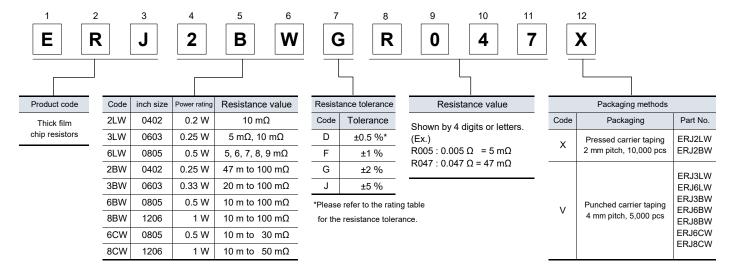
RoHS compliant

■ As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note: Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.

ERJ2LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW series
 High power (double-sided resistive elements structure) type>

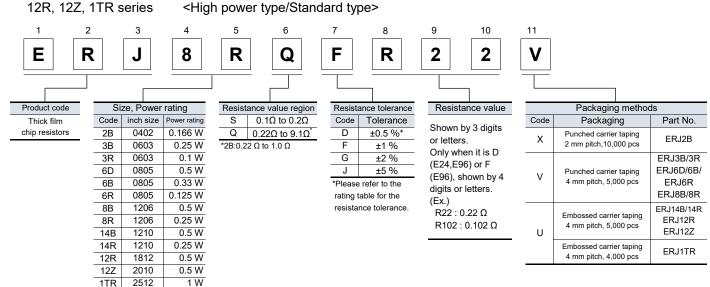


Thick Film Chip Resistors (Low Resistance Type)

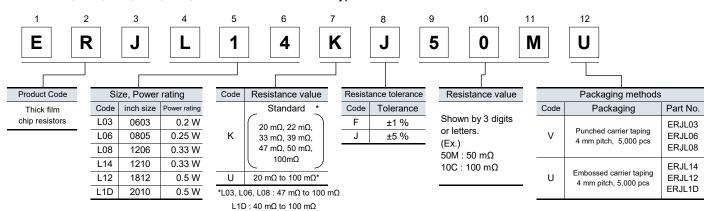
Explanation of part numbers

Note: Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.

• ERJ2BS/2BQ, 3BS/3BQ, 6BS/6BQ, 8BS/8BQ, 14BS/14BQ, 6D, 3R, 6R, 8R, 14R,



● ERJL03, L06, L08, L14, L12, L1D series <Low TCR type>



Ratings

< High power (double-sided resistive elements structure) type>

Part No. (inch size)	Power rating (70 °C) ^{*1} (W)	Resistance tolerance (%)	Resistance range ^{*2} (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range(℃)	AEC-Q200 Grade
ERJ2LW (0402)	0.2	±1, ±2, ±5	10 m	0 to +500		
ERJ3LW (0603)	0.25	±1, ±2, ±5	5 m	0 to +700	-55 to +125	Grade 1
LINGSLVV (0003)	0.23	11, 12, 13	10 m	0 to +300	-33 to 1123	Grade 1
ERJ6LW (0805)	0.5	±1, ±2, ±5	5, 6, 7, 8, 9 m	0 to +300		
ERJ2BW (0402)	0.25	±1, ±2, ±5	47 m to 100 m (E2	1) 0 to +300		
ERJ3BW (0603)	0.33	±1, ±2, ±5	20 m to 100 m (E2	1) $20 \text{ m}\Omega \le R < 39 \text{ m}\Omega : 0 \text{ to } +25$ $39 \text{ m}\Omega \le R \le 100 \text{ m}\Omega : 0 \text{ to } +15$		
ERJ6BW (0805)	0.5	±1, ±2, ±5	10 m to 100 m (E2	1) $ 10 \text{ m}\Omega \le R < 15 \text{ m}\Omega : 0 \text{ to } +30 $ $ 15 \text{ m}\Omega \le R \le 100 \text{ m}\Omega : 0 \text{ to } +20 $	-55 to +155	Grade 0
ERJ8BW (1206)	1	±1, ±2, ±5	10 m to 100 m (E2	10 m $\Omega \le R < 20$ m $\Omega : 0 \text{ to } +20$ 10 m $\Omega \le R < 47$ m $\Omega : 0 \text{ to } +15$ 47 m $\Omega \le R \le 100$ m $\Omega : 0 \text{ to } +10$	0	
ERJ6CW (0805)	0.5	±0.5, ±1, ±2, ±5	10 m to 30 m (E2	4) ±75	-55 to +125	Grade 1
ERJ8CW (1206)	1	±1, ±2, ±5	10 m to 50 m (E2	4) ±75	-55 10 +125	Grade I

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

^{*2:} Please contact us when resistors of irregular series are needed.

[•] Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value.

[·] Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

Ratings

<High power type>

Part No. (inch size)	Power rating (70 °C) ^{*1} (W)	Resistance tolerance (%)	Resistance range ^{*3} (Ω)		T.C.R. (×10 ⁻⁶ /K)	Category temperature range(℃)	AEC-Q200 Grade
ERJ2BS (0402)	0.166	±1, ±2, ±5	0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +300$		
ERJ2BQ (0402)	0.100	±1, ±2, ±3	0.22 to 1.0	(E24)	$0.22 \Omega \le R \le 1.0 \Omega : 0 \text{ to } +250$		
ERJ3BS (0603)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +300$		
ERJ3BQ (0603)	0.25	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +300$		
ER33BQ (0003)			1.0 to 9.1	(E24)	1.0 Ω ≤ R ≤ 9.1 Ω : ±200		
ERJ6DS (0805)			0.10 to 0.20	(E24 ^{*2})	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +150$		
ERJ6DQ (0805)	0.5	±0.5, ±1, ±2, ±5	0.22 to 9.1	(E24 ^{*2})	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +100$		
EN30DQ (0003)			0.22 (0 9.1	(⊏24)	1.0 Ω ≤ R ≤ 9.1 Ω : ±100		
ERJ6BS (0805)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +250$	-55 to +155	Grade 0
ERJ6BQ (0805)	0.33	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +250$		
ERJOBQ (0003)			1.0 to 9.1	(E24)	1.0 Ω ≤ R ≤ 9.1 Ω : ±200		
ERJ8BS (1206)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +250$		
ERJ8BQ (1206)	0.5	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +250$		
ERJODQ (1200)			1.0 to 9.1	(E24)	1.0 Ω ≤ R ≤ 9.1 Ω : ±200		
ERJ14BS (1210)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +200$		
ERJ14BQ (1210)	0.5	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +200$		
ENJ 140Q (1210)			1.0 to 9.1	(E24)	1.0 Ω ≤ R ≤ 9.1 Ω : ±100		

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

<Standard type>

Part No. (inch size)	Power rating (70 °C) ^{*1} (W)	Resistance tolerance (%)	Resistand range ^{*2} (Ω)	-	T.C.R. (×10 ⁻⁶ /K)	Category temperature range(℃)	AEC-Q200 Grade
ERJ3RS (0603)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +300$		
ERJ3RQ (0603)	0.1	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \le R < 1.0~\Omega~:0$ to +300		
LINUSING (0003)			1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 200$		
ERJ6RS (0805)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +250$		
ERJ6RQ (0805)	0.125	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \le R < 1.0~\Omega~:0$ to +250		
LINUINQ (0003)			1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 200$		
ERJ8RS (1206)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +250$		
ERJ8RQ (1206)	0.25	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \le R < 1.0~\Omega~:0$ to +250		
LINDING (1200)			1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 200$		
ERJ14RS (1210)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +200$		
ERJ14RQ (1210)	0.25	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \sim +200$	-55 to +155	Grade 0
LIN 141 Q (1210)			1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 100$		
ERJ12RS (1812)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +200$		
ERJ12RQ (1812)	0.5	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +200$		
LN312NQ (1012)			1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega$: ±100		
ERJ12ZS (2010)			0.10 to 0.20	(E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega : 0 \text{ to } +200$		
ERJ12ZQ (2010)	0.5	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +200$		
LN3122Q (2010)			1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 100$		
ERJ1TRS (2512)			0.10 to 0.20	(E24)	$0.10 \Omega \le R < 0.22 \Omega$: 0 to +200		
ERJ1TRQ (2512)	1	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22~\Omega \le R < 1.0~\Omega~:0$ to +200		
LIGHTING (2012)			1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega$: ±100		

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

^{*2:} E96 series resistance values are also available. Please contact us for details.

^{*3:} Please contact us when resistors of irregular series are needed.

[•] Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value.

[·] Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

^{*2:} Please contact us when resistors of irregular series are needed.

[•] Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\(Power Rating \times Resistance Value. \)

[·] Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

Thick Film Chip Resistors (Low Resistance Type)

Ratings

<Low TCR type>

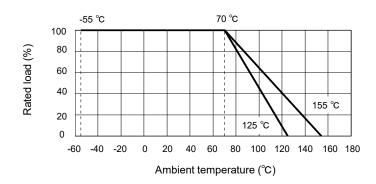
Part No. (inch size)	Power rating (70 °C)*1 (W)	Resistance tolerance (%)	Resistance range ^{*2} (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range(℃)	AEC-Q200 Grade
ERJL03 (0603)	0.2	±1, ±5	47 m to 100 m	±200		
ERJL06 (0805)	0.25	±1, ±5	47 m to 100 m	±100		
ERJL08 (1206)	0.33	0.33 ±1, ±5 47 m to 100 m		±100	-55 to +125	Grade 1
ERJL14 (1210)	0.33	±1, ±5	20 m to 100 m	D 4 47 m 0 + 1200	-55 to 1125	Grade 1
ERJL12 (1812)	0.5	±1, ±5	20 m to 100 m	R < 47 mΩ : ±300 R ≥ 47 mΩ : ±100		
ERJL1D (2010)	0.5	±1, ±5	40 m to 100 m	1 € 47 m2 . ±100		

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

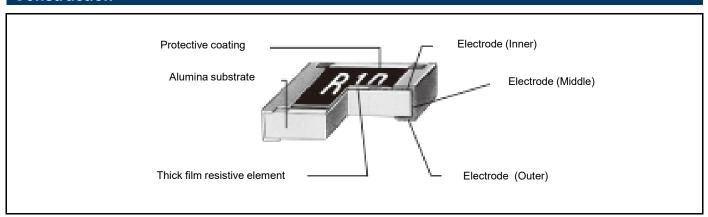
- · Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value.
- · Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

Power derating curve

For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



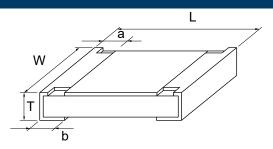
Construction



^{*2:} Standard R.V. : 20 m Ω , 22 m Ω , 33 m Ω , 39 m Ω , 47 m Ω , 50 m Ω , 100 m Ω , Custom R.V. : Each 1 m Ω within upper range.

Thick Film Chip Resistors (Low Resistance Type)

Dimensions (not to scale)



Unit : mm

	Dimensions								
Part No.	L	W	a	b	Т	(Reference) (g/1000 pcs)			
ERJ2LW	1.00±0.10	0.50+0.10/-0.05	0.25±0.10	0.25±0.10	0.40±0.05	0.8			
ERJ2BW	1.00±0.10	0.50+0.10/-0.05	0.24±0.10	0.24±0.10	0.35±0.05	0.8			
ERJ2B	1.00±0.10	0.50+0.10/-0.05	0.20±0.10	0.27±0.10	0.35±0.05	0.8			
ERJ3LW (5 mΩ)	1.60±0.15	0.80±0.15	0.50±0.20	0.50±0.20	0.55±0.10	3			
ERJ3LW (10 mΩ) ERJ3BW	1.60±0.15	0.80±0.15	0.40±0.20	0.40±0.20	0.55±0.10	3			
ERJ3R ERJ3B ERJL03	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2			
ERJ6LW	2.00±0.20	1.25±0.20	0.63±0.20	0.63±0.20	0.70±0.10	6			
ERJ6BW	2.00±0.20	1.25±0.20	0.55±0.20	0.55±0.20	0.65±0.10	6			
ERJ6CW (10 to 13 mΩ)	0.05.0.00	4.00.0.00	0.60±0.20	0.60±0.20	0.05.0.40				
ERJ6CW (15 to 30 mΩ)	2.05±0.20	1.30±0.20	0.45±0.20	0.45±0.20	- 0.65±0.10	6			
ERJ6D	2.00±0.20	1.25±0.10	0.40±0.20	0.55±0.25	0.60±0.10	5			
ERJ6R ERJ6B ERJL06	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	5			
ERJ8BW	3.20±0.20	1.60±0.20	1.00±0.20	1.00±0.20	0.65±0.10	13			
ERJ8CW (10 to 16 mΩ)	3.20±0.20	1.60±0.20	1.10±0.20	1.10±0.20	0.65±0.10	13			
ERJ8CW (18 to 50 mΩ)	3.20±0.20	1.60±0.20	0.60±0.20	0.60±0.20	0.65±0.10	13			
ERJ8R ERJ8B ERJL08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10			
ERJ14R ERJ14B ERJL14	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16			
ERJ12R ERJL12	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27			
ERJ12Z ERJL1D	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27			
ERJ1TR	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45			

Performance

• ERJ2LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW series <High power (double-sided resistive elements structure) type>

Test item	Performance requirements ⊿R	Test conditions			
Resistance Within specified tolerance		20 ℃			
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃			
Overload	±2 %	ERJ6LW : Rated voltag× 1.77, 5 s ERJ8BW (R > 0.05 Ω) : Rated voltag× 1.77, 5 s Other : Rated voltag× 2.0, 5 s			
Resistance to soldering heat	±1 %	270 ℃, 10 s			
Rapid change of temperature	±1 % ERJ2LW : ±2 %	–55 ℃ (30min.) / +155 ℃ (ERJ□LW, ERJ□CW : +125 ℃) (30 min.), 100 cycles			
High temperature exposure	±1 %	+155 ℃ (ERJ□LW, ERJ□CW : +125 ℃), 1000 h			
Damp Heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h			
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h			
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h			

• ERJ2BS/2BQ, 3BS/3BQ, 6BS/6BQ, 8BS/8BQ, 14BS/14BQ, 6D, 3R, 6R, 8R, 14R, 12R, 12Z, 1TR series <High power type/Standard type>

Test item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 °C / +125 °C
Overload	±2 %	Rated voltage× 2.5 (ERJ6D : ×1.77), 5 s
Resistance to soldering heat	±1 %	270 ℃, 10 s
Rapid change of temperature	±1 %	-55 °C (30 min.) / +155 °C (30 min.), 100 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp Heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

● ERJL03, L06, L08, L14, L12, L1D series < Low TCR type >

Test item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload	±2 %	Rated voltage× 2.5, 5 s
Resistance to soldering heat	±1 %	270 ℃, 10 s
Rapid change of temperature	±1 %	–55 ℃ (30 min.) / +125 ℃ (30 min.), 100 cycles
High temperature exposure	±1 %	+125 ℃, 1000 h
Damp Heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

INDUSTRY

Current Sensing Resistors, Metal Plate Type

ERJ MS, MB type

ERJ MS4, MB1 series



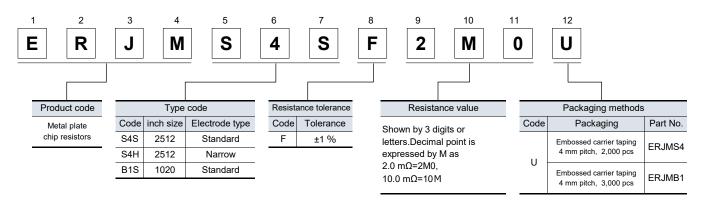
Features

- Ideal for current sensing solution
- Small case size with high power
- Metal plate bonding technology. Excellent long term stability
- Outer Resin with high heat dissipation. Wide temperature range (-65 °C to +170 °C)
- AEC-Q200 compliant
- RoHS compliant
- ISO9001, ISO/TS16949 certified
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note: Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.

±75



Ratings Category Terminal temp. Power rating Resistance Resistance T.C.R. AEC-Q200 temperature Part No. upper limit (70 ℃) range tolerance (inch size) (×10⁻⁶/K) range Grade (℃) (W) $(m\Omega)$ (%) (\mathcal{C}) **ERJMS4S** 3 1, 2, 3, 4 F: ±1 ±75 (2512)130 ERJMS4H 3 5, 6 F: ±1 ±75 -65 to +170 Grade 0 (2512)2 100 7, 8, 9, 10 F: ±1 ±75

F: ±1

1, 2, 3, 4, 5

Power derating curve

If the terminal temperature of the resistor is more than terminal temperature upper limit value of the rated table, please reduce the rated power according to the Power Derating Curve shown in the figure on the right.

2

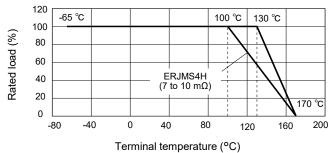
<Supplemented>

ERJMB1S

(1020)

In the case of the temperature measurement of the terminal portion of the resistor, Please perform under the following conditions.

- 1) Terminal temperature measurement, please apply the temperature of the higher of either the left or right electrode upper surface of the resistor.
- 2) Please measure the temperature of the resistor in the land pattern printed of circuit board and plan to use by real conditions

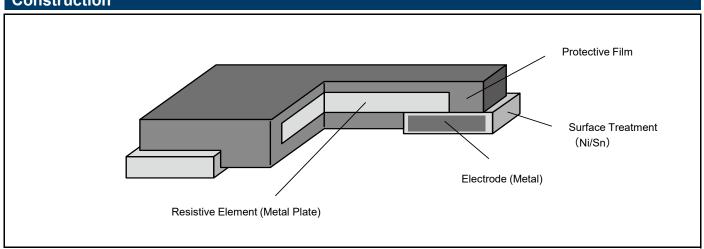


130

^{*} Please contact us when resistors of irregular series are needed.

Current Sensing Resistors, Metal Plate Type

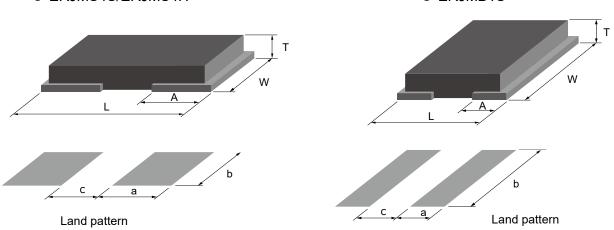
Construction



Dimensions in mm (not to scale), Recommended land pattern







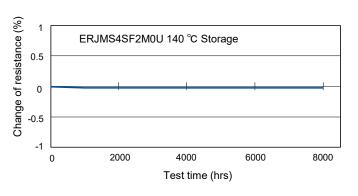
Unit : mm

Part No.		Dime	Recom	Mass (Weight) (Reference)						
	L	W	Α	Т	а	b	С	(g/1000 pcs)		
ERJMS4S	6.40±0.25	3.20±0.25	2.20±0.25	1.20±0.15	2.7	3.4	2.0	120		
ERJMS4H	6.40±0.25	3.20±0.25	1.25±0.25	1.20±0.15	1.7	3.4	4.0	115		
ERJMB1S	2.55±0.25	5.00±0.25	0.68 +0.15/-0.20	0.90±0.15	1.15	5.5	1.1	40		

Typical temp. dependence of electrical resistance

Change of resistance (%) 0.5 0 -0.5 -80 -60 -40 -20 20 40 60 80 100 120 140 160 180 Temperature (°C)

Long-term stability



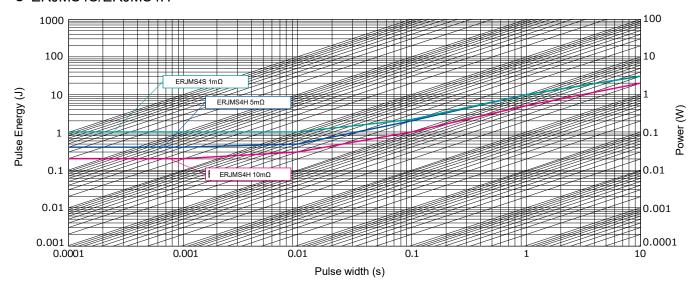
Maximum pulse energy respectively pulse power for continuous operation

Referance Data

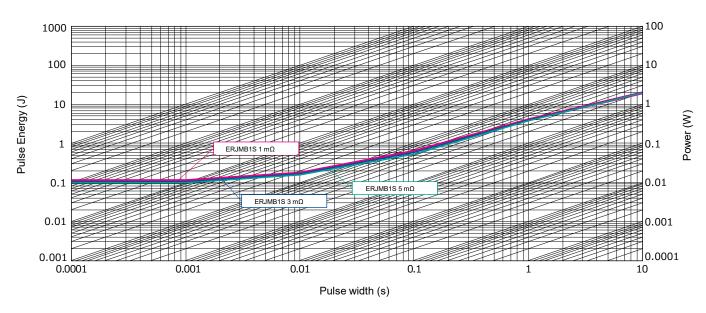
Condition: Room Temperature, OFF: 10 s, 1000 cycle, Wave form: Square

Change of Resistance = ±1 %

ERJMS4S/ERJMS4H



• ERJMB1S



Performance (AEC-Q200)

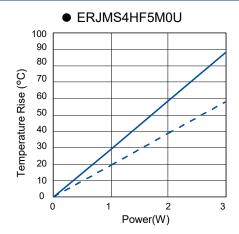
ERJMS4S/ERJMS4H

Test item	Performance requirements ⊿R Typical value ⊿F		Test condition	
Thermal shock	±1 %	0.20 %	-55 ℃ / +155 ℃, 1000 cycles	
Overload	±0.5 %	0.10 %	Rated power x 3, 5 s	
Solderability	> 95% coverage	> 95% coverage	245 ℃, 3 s	
Resistance to solvents	No damage	No damage	MIL-STD-202 method 215, 2.1a, 2.1d	
Low temperature storage and operation	±0.5 %	0.03 %	–65 ℃, 24 h	
Resistance to soldering heat	±0.5 %	0.10 %	MIL-STD-202 method 210 (260 ℃, 10 s)	
Moisture resistance	±0.5 %	0.10 %	MIL-STD-202 method 106	
Shock	±0.5 %	0.10 %	MIL-STD-202 method 213-A	
Vibration, High frequency	±0.5 %	0.05 %	10 to 2000 (Hz)	
Life	±1 %	0.30 %	70 ℃, Rated Power, 2000 h	
Storage life at elevated temperature	±1 %	0.30 %	170 ℃, 2000 h	
High temperature characteristics	±0.5 %	0.05 %	140 ℃, 2000 h	
Frequency characteristics	< 5 nH	< 2 nH	Inductance	

ERJMB1

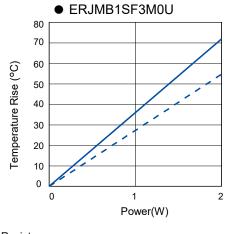
Test item	Performance requirements ⊿R	Typical value ⊿R	Test condition
Thermal shock	±1 %	0.30 %	-55 ℃ / +155 ℃, 1000 cycles
Overload	±1 %	0.30 %	Rated power x 2.5, 5 s
Solderability	> 95% coverage	> 95% coverage	245 ℃, 3 s
Resistance to solvents	No damage	No damage	MIL-STD-202 method 215, 2.1a, 2.1d
Low temperature storage and operation	±0.5 %	0.03 %	–65 ℃, 24 h
Resistance to soldering heat	±0.5 %	0.10 %	MIL-STD-202 method 210 (260 ℃, 10 s)
Moisture resistance	±0.5 %	0.10 %	MIL-STD-202 method 106
Shock	±0.5 %	0.10 %	MIL-STD-202 method 213-A
Vibration, High frequency	±0.5 %	0.05 %	10 to 2000 (Hz)
Life	±1 %	0.30 %	70 ℃, Rated Power, 2000 h
Storage life at elevated temperature	±1 %	0.30 %	170 ℃, 2000 h
High temperature characteristics	±0.5 %	0.05 %	140 ℃, 2000 h
Frequency characteristics	< 5 nH	< 2 nH	Inductance

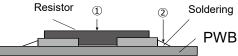
Temperature rise



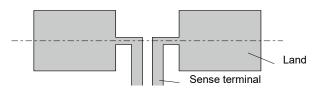
<Condition>

Base material: FR-4 (t 1.6 mm) Copper Thickness : 70 µm, Two layer





Sense terminal-Layout



High Power Chip Resistors (Wide Terminal Type)

ERJ A, B type

ERJ A1, B1, B2, B3 series



Features

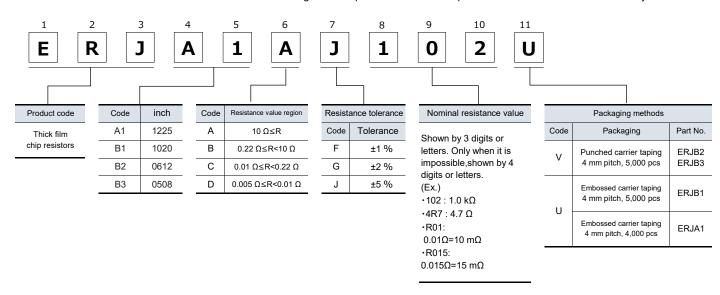
- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 compliant
- RoHS compliant

Recommended applications

- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems.
- Current sensing for power supply circuits in a variety of equipment.
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note: Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



High Power Chip Resistors (Wide Terminal Type)

Ratings

Part No. (inch size)	Power rating*1 (W)	Rated ambient temperature*2	Rated terminal part temperature*2	Limiting element voltage ^{*3} (V)	Maximum overload voltage*4 (V)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC- Q200 Grade		
ERJA1	1.33	70		200	400	±1	100m to 10k (E24)	±100				
(1225)	1.33	70	-	200	400	±2, ±5	10m to 10k (E24)	10mΩ≤R<100mΩ : ±350 100mΩ≤R≤10kΩ : ±200				
						±1	40 4 40	±1 % : 10mΩ≤R<22mΩ : 0 to +350				
ERJB1	2 (R≤10Ω) 70	70	0 125	200	400	±2, ±5	10m to 10 (E24)	22mΩ≤R<47mΩ : 0 to +200 47mΩ≤R<100mΩ : 0 to +150 100mΩ≤R≤10kΩ : ±100				
(1020)	1	70	95			±1	11 to 10k	±2 %, ±5 % : 10mΩ≤R<22mΩ : 0 to +350				
	(R>10Ω)	70	93			±2, ±5	(E24)	22mΩ≤R<100mΩ : 0 to +200 100mΩ≤R≤10kΩ : ±200				
	1.5 (R≤1kΩ)	-	125			±1 ±2, ±5	10m to 1k (E24)	±1 % :				
	0.75 (R>1k Ω)	-	90			±1 ±2, ±5	1.1k to 1M (E24)	10mΩ≤R<22mΩ : 0 to +300 22mΩ≤R<47mΩ : 0 to +200				
						-		±1	10m to 10 (E24)	47 mΩ \leq R $<$ 100mΩ : 0 to +150 100 mΩ \leq R \leq 220mΩ : 0 to +100	− 55 ~ + 155	Grade 0
ERJB2 (0612)	1 (R≤10Ω)	70	-	200	400	400	±5	5, 6, 7, 8, 9,10m to 10 (E24)	$220m\Omega \le R \le 1M\Omega : \pm 100$ $\pm 2 \%, \pm 5 \% :$ $5m\Omega \le R < 22m\Omega : 0 \text{ to } +300$ $22m\Omega \le R < 47m\Omega : 0 \text{ to } +200$ $47m\Omega \le R < 100m\Omega : 0 \text{ to } +150$ $100m\Omega \le R < 220m\Omega : 0 \text{ to } +200$			
	0.75 (R>10Ω)	70				±1 ±2, ±5	11 to 1M (E24)	220mΩ≤R≤1MΩ : ±200				
	1	-	105		50 200	±1 ±2, ±5	20m to 10 (E24)	$\pm 1\%$: $20m\Omega \le R < 47m\Omega$: 0 to +300 $47m\Omega \le R < 1\Omega$: 0 to +200				
ERJB3 (0508)	0.5 (R≤1Ω)	70	-	150		±1 ±2, ±5	20m to 1 (E24)	1Ω≤R≤10Ω : ±100 ±2 %, ±5 % : 20mΩ≤R<47mΩ : 0 to +300				
	0.33 (R>1Ω)	70	-			±1 ±2, ±5	1.1 to 10 (E24)	47mΩ≤R<1Ω: 0 to +200 1Ω≤R≤10Ω: ±200				

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

^{*2:} If there is a doubt whether the rated ambient temperature or the rated terminal part temperature is used, give priority to the rated terminal part temperature.

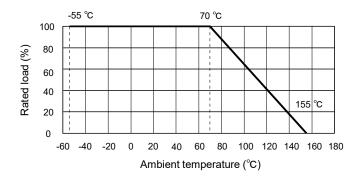
^{*3:} Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

^{*4:} Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

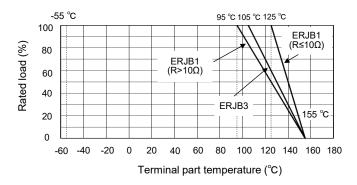
Ratings

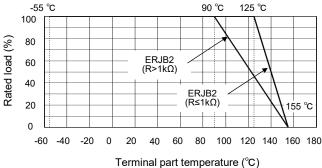
Power derating curve

- For resistors operated in ambient rated ambient temperature, power rating shall be derated in accordance with the figure below.
 - In addition, please use under the condition that the product temperature is below the upper category temperature.

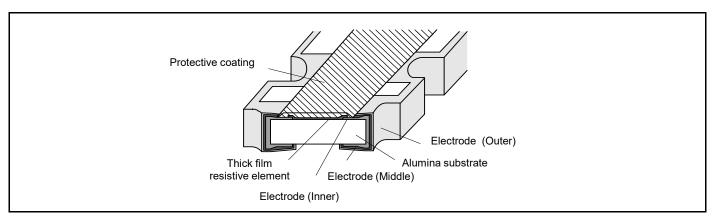


- For resistors operated in ambient rated terminal part temperature, power rating shall be derated in accordance with the figure below.
 - In addition, please use under the condition that the product temperature is below the upper category temperature.



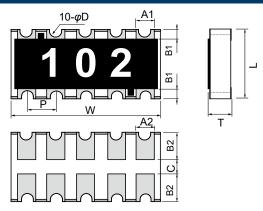


Construction (Example : ERJA1 type)



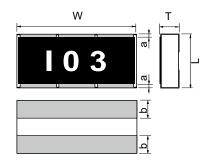
High Power Chip Resistors (Wide Terminal Type)

Dimensions (not to scale)



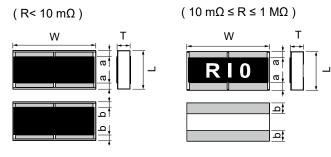
Unit : mm

Part No.	Dimensions						
Fait No.	L	W	A ₁	B ₁	Т	(Reference) (g/1000 pcs)	
	3.20±0.20	6.40±0.20	0.70±0.20	0.45±0.20	0.55±0.10		
ERJA1	A_2	B_2	Р	øD	С	40	
	0.70±0.20	1.25±0.15	1.27±0.10	0.30+0.10/-0.20	0.4 min.		



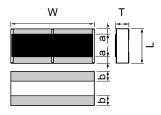
Unit : mm

Part No.	Dimensions						
Fait No.	L	W	а	b	T	(Reference) (g/1000 pcs)	
ERJB1	2.50±0.20	5.00±0.20	0.25±0.20	0.90±0.20	0.55±0.20	27	



Unit : mm

Part No.		Dimensions					
ERJB2	L	W	а	b	Т	(Reference) (g/1000 pcs)	
5 mΩ≤R<10 mΩ			0.30±0.20	0.30±0.20	0.65±0.15		
10 mΩ≤R<220 mΩ	1.60±0.15	3.20±0.20	0.30±0.20	0.50±0.20	0.55±0.15	11	
220 mΩ≤R≤1 MΩ			0.25±0.20	0.50±0.20	0.55±0.15		

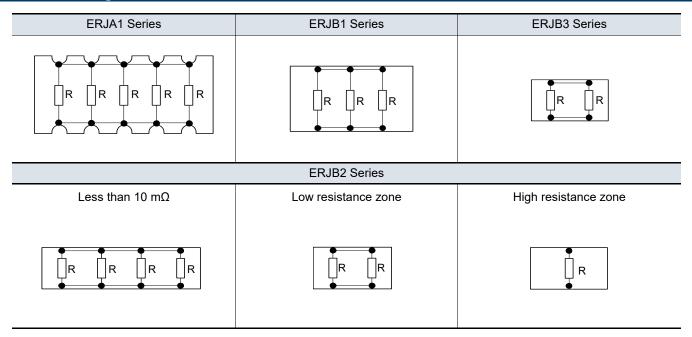


Unit: mm

Part No.	Dimensions							
Fait No.	L	W	а	b	Т	(Reference) (g/1000 pcs)		
ERJB3	1.25±0.10	2.00±0.15	0.25±0.20	0.40±0.20	0.50±0.10	4.8		

High Power Chip Resistors (Wide Terminal Type)

Circuit configuration



Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload	±2 %	ERJA1, ERJB1 (1W): Rated voltag x 2.5, 5 s ERJB2 (0.75 W): Rated voltag x 2.2, 5 s ERJB1 (2 W), ERJB2 (1.5 W, 1 W), ERJB3: Rated voltag x 2.0, 5 s
Resistance to soldering heat	±1 %	270℃, 10 s
Rapid change of temperature	±2 %	-55 °C (30 min.) / +125 °C (30 min.), 1000 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity 1 (Applicable to rated ambient temperature-regulated products)	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage 1.5 h ON / 0.5 h OFF cycle, 1000 h
Load life in humidity 2 (Applicable to rated ambient temperature-regulated products)	±3 %	85 °C, 85 %RH, Rated power 10%, Continuously power, 1000 h
Durability at rated ambient temperature or rated terminal part temperature	±3 %	Rated ambient temperature or rated terminal part temperature, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

INDUSTRY

Low TCR High Power Chip Resistors (Wide Terminal Type)



ERJ D type

ERJ D1, D2 series

Features

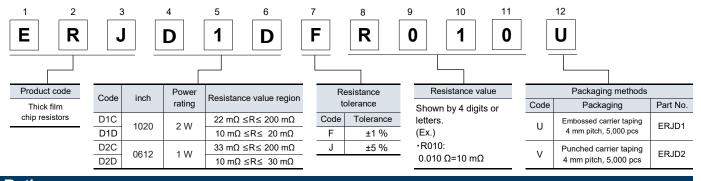
- Achieved High power and low TCR (±100×10⁻⁶/K) using wide terminal electrode structure and original material
- Suitable for small size/high power current detection (Low TCR enables high accuracy of current detection)
- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 compliant
- RoHS compliant

Recommended applications

- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems.
- Current sensing for power supply circuits in a variety of equipment.
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note: Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



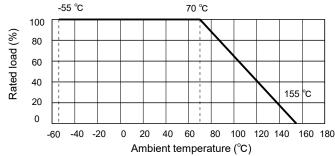
Ratings

Part No. (inch size)	Power rating (70 ℃)*1 (W)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC- Q200 Grade
ERJD1 (1020)	2	±1, ±5	10 m to 200 m (E24)	±100	-55 to +155	Grade 0
ERJD2 (0612)	1	±1, ±5	10 m to 200 m (E24)	±100	-55 10 +155	Grade 0

- *1: Use it on the condition that the case temperature is below the upper category temperature.
 - · Please contact us when resistors of irregular series are needed.
 - Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\(Power Rating \times Resistance Value. \)
 - · Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV.

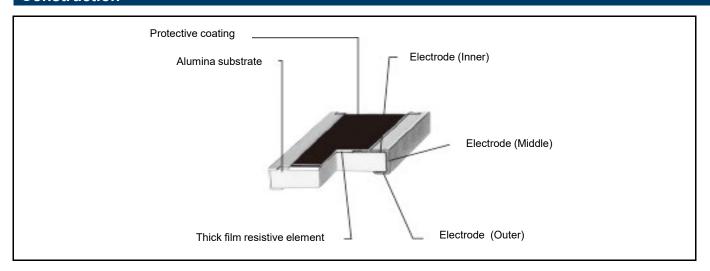
Power derating curve

For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.

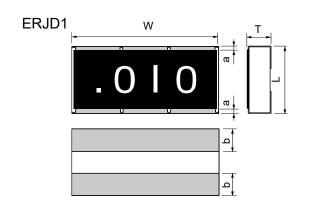


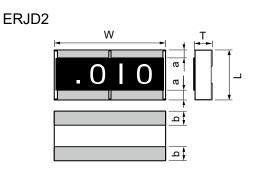
Low TCR High Power Chip Resistors (Wide Terminal Type)

Construction



Dimensions (not to scale)

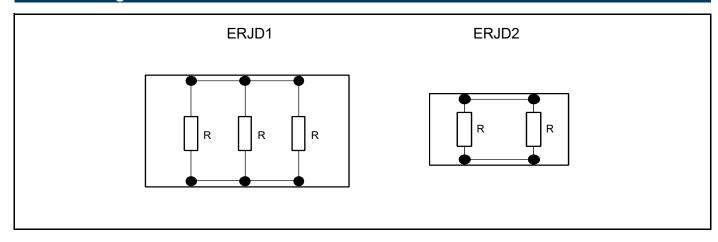




Unit : mm

Part No.	Dimensions							
Fait No.	Г	W	а	b	Т	(Reference) (g/1000 pcs)		
ERJD1	2.50±0.20	5.00±0.20	0.30±0.20	0.90±0.20	0.60±0.20	27		
ERJD2	1.60±0.15	3.20±0.20	0.30±0.20	0.50±0.20	0.65±0.15	11		

Circuit configuration



Low TCR High Power Chip Resistors (Wide Terminal Type)

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload	±2 %	Rated voltag x 2.0, 5 s
Resistance to soldering heat	±1 %	270 ℃, 10 s
Rapid change of temperature	±2 %	-55 °C (30 min.) / +125 °C (30 min.), 1000 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

INDUSTRY

Anti-Surge Thick Film Chip Resistors

ERJ P, PA,PM type

ERJ PA2, PA3, P03, P06, P08, PM8, P14 series



Features

• ESD surge characteristics superior to standard metal film resistors

High reliability : Metal glaze thick film resistive element and three layers of electrodes

Suitable for both reflow and flow soldering

High power 0.20 W: 0603 inch / 1608 mm size (ERJP03)

0.20 W: 0402 inch / 1005 mm size (ERJPA2) 0.33 W: 0603 inch / 1608 mm size (ERJPA3)

0.50 W: 0805 inch / 2012 mm size (ERJP06), 1210 inch / 3225 mm size (ERJP14)

0.66 W: 1206 inch / 3216 mm size (ERJP08)

High precision, High voltage, High resistance value (ERJPM8)

: Limiting element voltage 500 V, Resistance tolerance ±1 %, TCR ±100 (x 10⁻⁶ / K)

Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C

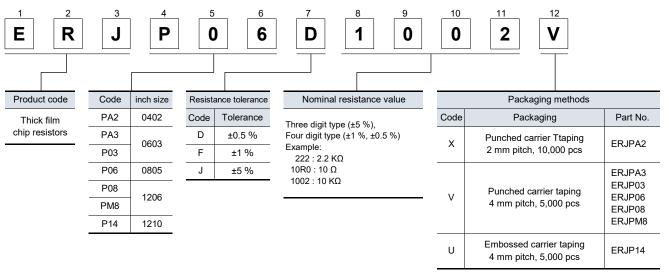
AEC-Q200 compliant

RoHS compliant

■ As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note: Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



Anti-Surge Thick Film Chip Resistors

Ratings

Part No.	- 10.09															
ERJPA2 (0402) 100		rating*1	ambient temperature*2	terminal part temperature ^{*2}	element voltage ^{*3}	overload voltage ^{*4}	tolerance	range		temperature	Q200					
ERIPA2 (0402) 0.25 - 100							±0.5, ±1	(E24, E96)								
100 100		0.20	70	-	50	100	±5	expansion 1 to 1M			Grade 1					
150 150	(0402)				00	100	±0.5, ±1				Grado :					
ERJPA3 (0603)		0.25	-	100			±5	expansion 1 to 1M								
ERJPO3 (0603) 0.33 - 130 150 200 200 20.5, ±1 (10.1 sM (E24, E96) (E24,		0.25	105				±0.5, ±1									
0.33 - 130 \frac{\pmu}{\pmu} \frac{\pmu}	ERJPA3	0.25	105	-	150 20	150 2	150	150	150	000	±5		±0.5, ±1 : ±100			
ERJP08 (0805) 0.50 70 125 500 1000 ±1 10 to 1M (E24, E96) ±100 100 sR × ±200 100 sR × ±	(0603)			100						130	130	130	130	130	200	±0.5, ±1
ERJP08 (1206) 0.50 70 125 500 1000 ±1 1.02 100 to 1M (E24, E96) ±150 ±100 ±		0.33	-	130			±5	-								
Company Com					150	150	150					±0.5		±150	-55 to +155	
±5 (E24)		0.20	70	-				200	±1		R<10Ω : –150 to +400					
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$							±5		10Ω≤R :±200							
(0805)							±0.5, ±1				Grade 0					
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		0.50	70	115	400	600	±5		10Ω≤R<33Ω :±300							
(1206) 0.66 70 125 500 1000 ±5 1 to 10M (E24) 10Ω≤R : ±200 ERJPM8 (1206) 0.66 70 125 500 1000 ±1 1.02M to 10M (E24, E96) ±100 ERJP14 (1210) 0.50 70 - 200 400 ±5 1 to 1M (E24, E96) ±100	FRJP08						±0.5, ±1		±100							
ERJPM8 (1206) 0.66 70 125 500 1000 ±1 1.02M to 10M (E24, E96) ±100 ERJP14 (1210) 0.50 70 - 200 400 ±5 1 to 1M (R<10Ω: -100 to +600)		0.66	70	125	500	1000	±5									
ERJP14 (1210) 0.50 70 - 200 400 ±0.5, ±1 (E24, E96) ±100 (E24, E96) ±100 (E24, E96) (E2		0.66	70	125	500	1000	±1									
(1210) 0.50 70 - 200 400 ±5 1 to 1M R<10Ω : -100 to +600	ERJP14	0.50	70		000	400	±0.5, ±1		±100							
		0.50	70	-	200	400	±5									

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

^{*2:} If there is a doubt whether the rated ambient temperature or the rated terminal part temperature is used, give priority to the rated terminal part temperature.

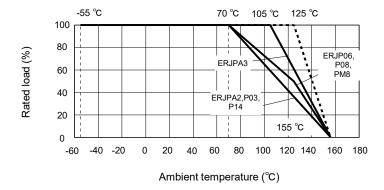
^{*3:} Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

^{*4:} Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

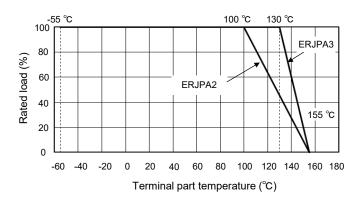
Ratings

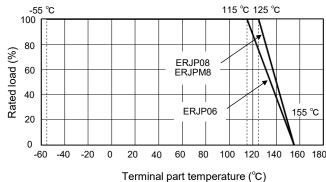
Power derating curve

- •For resistors operated in ambient rated ambient temperature, power rating shall be derated in accordance with the figure below.
 - In addition, please use under the condition that the product temperature is below the upper category temperature.
 - % When the temperature of ERJP14 is 155 $^{\circ}$ C or less, the derating start temperature can be changed to 125 $^{\circ}$ C. (See the dotted line)

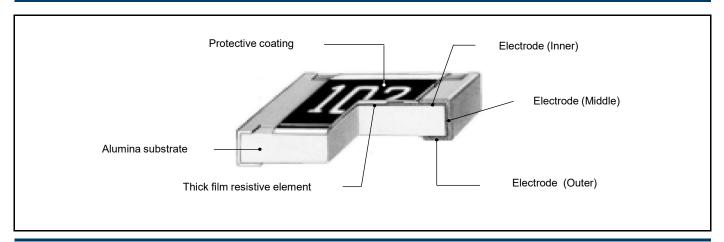


- •For resistors operated in ambient rated terminal part temperature, power rating shall be derated in accordance with the figure below.
 - In addition, please use under the condition that the product temperature is below the upper category temperature.

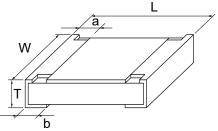




Construction



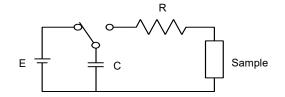
Dimensions (not to scale)



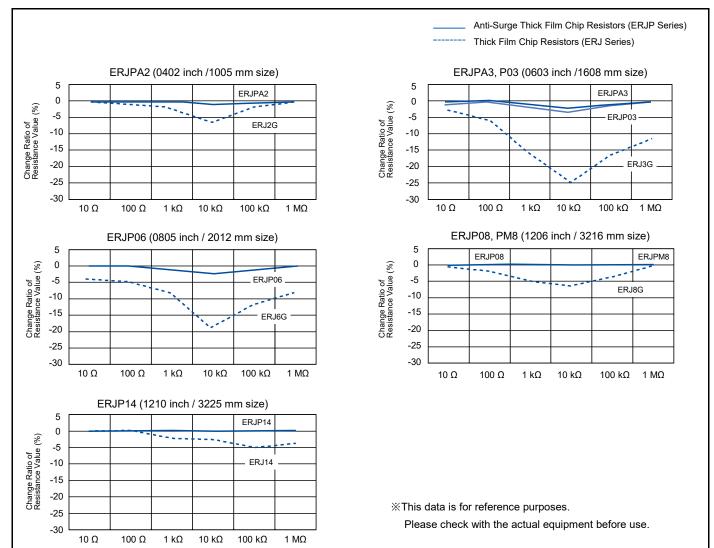
Unit: mm

Part No.	Dimensions								
Fait No.	L	W	а	b	Т	(Reference) (g/1000 pcs)			
ERJPA2	1.00±0.05	0.50±0.05	0.20±0.15	0.25±0.10	0.35±0.05	0.8			
ERJPA3	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.25±0.10	0.45±0.10	2			
ERJP03	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.30±0.15	0.45±0.10	2			
ERJP06	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4			
ERJP08,PM8	3.20+0.05/-0.20	1.60+0.05/-0.15	0.40±0.20	0.50±0.20	0.60±0.10	10			
ERJP14	3.20±0.20	2.50±0.20	0.35±0.20	0.50±0.20	0.60±0.10	16			

ESD Characteristic



Size (inch)	0402	0603, 0805, 1206, 1210
R	1.5 kΩ	R=0 Ω (\leq 1.5 kΩ) / 150 Ω > 1.5 kΩ)
С	100 pF	150 pF
Е	±1 kV	±3 kV



Anti-Surge Thick Film Chip Resistors

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +155 ℃ (ERJPA2 : +125 ℃)
	±2 %	ERJP06 : Rated voltag× 1.77, 5 s
Overload	Only when it is ERJP03 (D),	ERJPA2, ERJPA3, ERJP08, ERJPM8: Rated voltag× 2.0, 5 s
	P14 (D) : ±0.5 %	ERJP03, ERJP14 : Rated voltag× 2.5, 5 s
Resistance to soldering heat	D: ±0.5 %, F, J: ±1 %	270 ℃, 10 s
Rapid change of temperature	±1 %	–55 ℃ (30min.) / +155 ℃ (ERJPA2 : +125 ℃) (30min.), 100 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity 1 (Applicable to rated ambient temperature-regulated products)	±3 % Only when it is ERJP03 (D), P14 (D) : ±1 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Load life in humidity 2 (Applicable to rated ambient temperature-regulated products)	±3 %	85 °C, 85 %RH, Rated power 10%, Continuously power, 1000 h
Durability at rated ambient temperature or rated terminal part temperature	±3 % Only when it is ERJP03 (D), P14 (D) : ±1 %	Rated ambient temperature or rated terminal part temperature, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h



Anti-Surge Thick Film Chip Resistors (Double-sided resistive elements structure)

ERJ P□W type **ERJ P6W** series

Features

- ESD surge characteristics superior to standard metal film resistors
- Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- : 0.50 W, 2012(0805) size(ERJP6W) High power
- : 1.5 times higher than 0805 inch size Anti-Surge thick film chip High pulse characteristics

resistors (ERJP06)

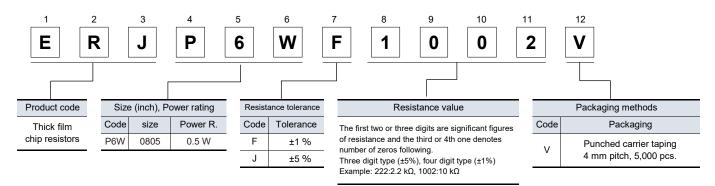
 Reference standards : IEC 60115-8, JIS C 5201-8, EIAJ RC-2134B

RoHS compliant

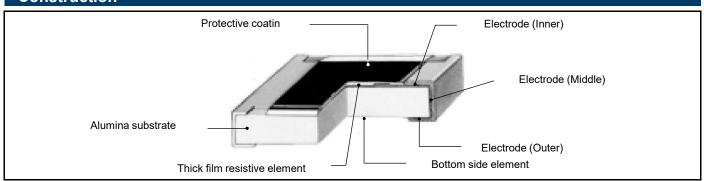
As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

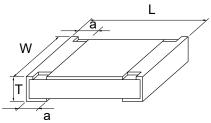
Note: Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



Construction



Dimensions in mm (not to scale)



Unit : mm

					011101
Typo		Dimer	nsions		Mass (Weight)
Туре	L	W	а	T	(g/1000 pcs)
ERJP6W (0805)	2.00±0.20	1.25±0.20	0.35±0.20	0.65±0.10	6

Anti-Surge Thick Film Chip Resistors (Double-sided resistive elements structure)

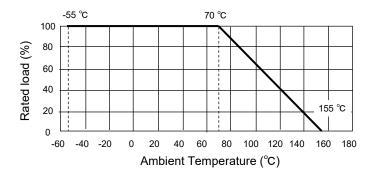
Ratings

Part No. (inch size)	Power rating ^{*1} (70 ℃) (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3}	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (°C)
ERJP6W (0805)	0.5	0.5 150	200	± 1	10 to 1 M (E24,E96)	± 200	-55 to +155
	0.3	130	200	± 5	1 to 1 M R < 10 Ω : -100 to +600	R < 10 Ω : -100 to +600	-55 to +155
					(E24)	10 Ω ≦ R : ±200	

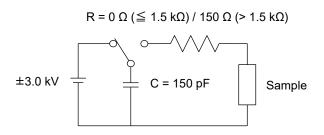
^{*1:} Use it on the condition that the case temperature is below 155 $^{\circ}$ C.

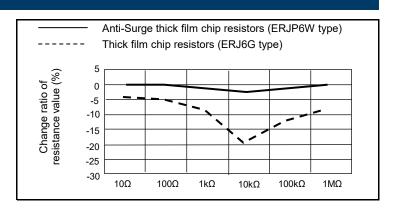
Power derating curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure below.



ESD Characteristic





^{*2:} Overload (Short-time Overload) test voltage (SOTV) shall be determined from SOTV=2.5 × Power rating or max. Over load voltage listed above whichever less.

^{*3:} Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=/Power Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.

INDUSTRY

Anti-Pulse Thick Film Chip Resistors

ERJ T type

ERJ T06, T08, T14 series

ERJ T14L series



Features

Anti-Pulse characteristics
 High pulse characteristics achieved by the optimized trimming specifications (ERJT06, T08, T14)

• Further high pulse characteristics achieved by trimming-less specifications (ERJT14L)

High reliability : Metal glaze thick film resistive element and three layers of electrodes

Suitable for both reflow and flow soldering

• High power 0.25 W: 0805 inch /2012 mm size(ERJT06)

0.33 W: 1206 inch /3216 mm size(ERJT08)

0.50 W: 1210 inch /3225 mm size(ERJT14, ERJT14L)

• Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C

AEC-Q200 compliant

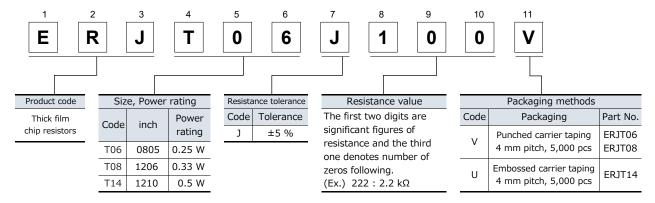
RoHS compliant

As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

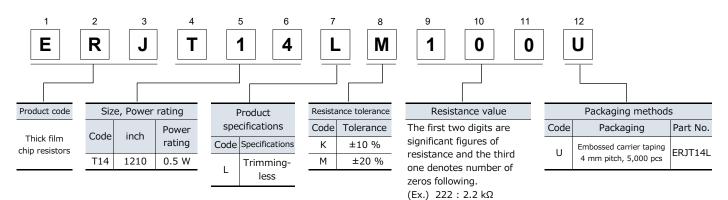
Explanation of part numbers

Note: Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.

ERJT06, T08, T14 series



• ERJT14L series



* Please contact us for 0805 (inch) and 1206 (inch) size trimming-less types.

Anti-Pulse Thick Film Chip Resistors

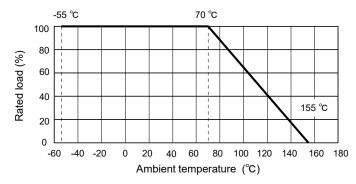
Ratings

Part No. (inch size)	Power rating ^{*1} (70 ℃)(W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJT06 (0805)	0.25	150	200	±5	1 to 1 M (E24)	R<10 Ω : $-100 \text{ to } +600$ 10 Ω≤R<33 Ω : ± 300 33 Ω≤R : ± 200		
ERJT08 (1206)	0.33	200	400	±5	1 to 1 M (E24)	R<10 Ω : -100 to +600 10 Ω≤R : ±200	-55 to +155	Grade 0
ERJT14 (1210)	0.50	200	400	±5	1 to 1 M (E24)	R<10 Ω : -100 to +600 10 $\Omega \le R$: ±200		
ERJT14L (1210)	0.50	200	400	±10 ±20	1 to 1 M (E12)	R<10 Ω : -100 to +600 10 Ω≤R : ±200		

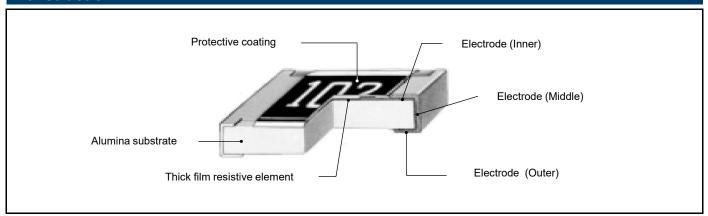
^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

Power derating curve

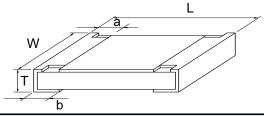
For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



Construction



Dimensions (not to scale)



Unit : mm

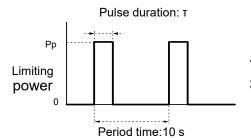
David Nia	Dimensions						
Part No.	L	W	а	b	Т	(Reference) (g/1000 pcs)	
ERJT06	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4	
ERJT08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.40±0.20	0.50±0.20	0.60±0.10	10	
ERJT14 ERJT14L	3.20±0.20	2.50±0.20	0.35±0.20	0.50±0.20	0.60±0.10	16	

^{*2:} Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

^{*3:} Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Limiting power curve

• In rush pulse Characteristic

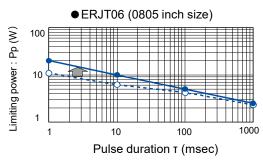


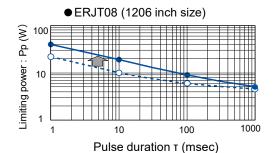
Test cycle: 1000 cycles

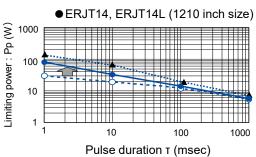
Spec : Resistance value = within ±5 %



 \bigcirc : Thick Film Chip Resistors(Series ERJ : 1 Ω)







- %This data is for reference purposes.
 Please check with the actual equipment before use.
- ※ Please contact us for 0805 (inch) and 1206 (inch) size trimming-less types.

remonitative		
Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +155 ℃
Overload	±2 %	Rated voltage× 2.5, 5 s
Resistance to soldering heat	±1 %	270 ℃±3 ℃, 10 s ±1 s
Rapid change of temperature	±1 %	-55 ℃ (30 min.) / +155 ℃ (30 min.), 100 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃ ±2 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 $^{\circ}$ C ±2 $^{\circ}$ C, 90 $^{\circ}$ 6 to 95 $^{\circ}$ RH, Rated voltage , 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70℃	±3 %	70 ℃ ±2 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

INDUSTRY

Anti-Sulfurated Thick Film Chip Resistors

ERJ S type (Au-based inner electrode type)

ERJ S02, S03, S06, S08, S14 series

ERJ S12, S1D, S1T series

ERJ U type (Ag-Pd-based inner electrode type)

ERJ U0X, U01, U02, U03, U06, U08, U14 series

ERJ U12, U1D, U1T, U6S, U6Q series

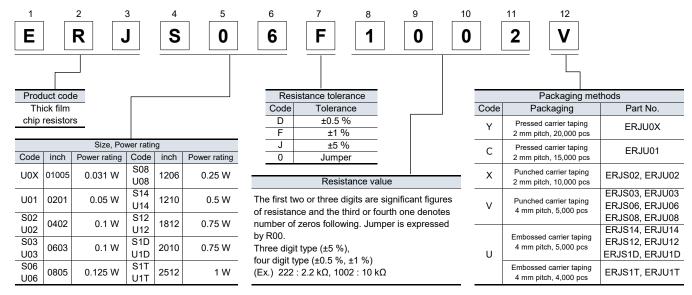
Features

- High resistance to sulfurization achieved by adopting an Au-based inner electrode (Series ERJS) and Ag-Pd-based inner electrode (Series ERJU)
- High reliability : Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- Low resistance type : ERJU6S, U6Q series : 0.1 Ω to 1 Ω
- Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant (except ERJU0X, ERJU01)
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

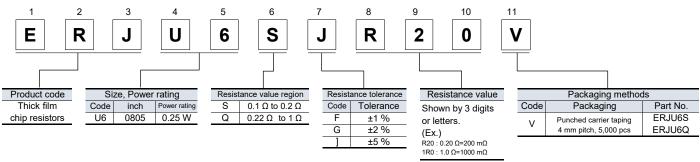
Explanation of part numbers

Note: Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.

• ERJS02 to ERJS1T, ERJU0X to ERJU1T series







Anti-Sulfurated Thick Film Chip Resistors

Rating	S								
Part No. (inch size)	Power rating ^{*1} (70 ℃)(W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	rar	stance nge Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC- Q200 Grade
ERJU0X				±1	10 to 1 M	(E24, E96)	R<10 Ω : –100 to +600		
(01005)	0.031	15	30				10 Ω≤R<100 Ω :±300		
				±5	1 to 1 M	(E24)	100 Ω≤R :±200	-55 to +125	-
ERJU01	0.05	25	50	±1	10 to 1 M	(E24, E96)	R<10 Ω : -100 to +600		
(0201)				±5	1 to 1 M	(E24)	40.04.4440		
ERJS02	0.4	50	400	±0.5, ±1	1 to 1 M	(E24, E96)	10 Ω to 1 MΩ : ±200		
ERJU02 (0402)	0.1	50	100	±5	1 to 3.3 M	(E24)	1 MΩ <r +150<="" -400="" :="" td="" to=""><td></td><td></td></r>		
ERJS03				±0.5, ±1	1 to 1 M	(E24, E96)			
ERJU03 (0603)	0.1	75	150	±5	1 to 10 M	(E24)			
ERJS06				±0.5, ±1	1 to 1 M	(E24, E96)			
ERJU06 (0805)	0.125	150	200	±5	1 to 10 M	(E24)			
ERJS08				±0.5, ±1	1 to 1 M	(E24, E96)			
ERJU08 (1206)	0.25	200	400	±5	1 to 10 M	(E24)	R<10 Ω : –100 to +600		
ERJS14				±0.5, ±1	1 to 1 M	(E24, E96)		-55 to +155	Grade 0
ERJU14 (1210)	0.5	200	400	±5	1 to 10 M	(E24)	10 Ω to 1 MΩ : ±200 (± 5 %) : ±100 (±0.5 %, ±1 %)		
ERJS12				±0.5, ±1	1 to 1 M	(E24, E96)	(10.5 70, 11 70)		
ERJU12 (1812)	0.75	200	500	±5	1 to 10 M	(E24)	1 MΩ <r +150<="" -400="" :="" td="" to=""><td></td><td></td></r>		
ERJS1D				±0.5, ±1	1 to 1 M	(E24, E96)			
ERJU1D (2010)	0.75	200	500	±5	1 to 10 M	(E24)			
ERJS1T				±0.5, ±1	1 to 1 M	(E24, E96)	1		
ERJU1T (2512)	1.0	200	500	±5	1 to 10 M	(E24)			

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

[Low resistance type]

Part No. (inch size)	Power rating ^{*1} (70 ℃)(W)	Resistance tolerance (%)	Resistance range (Ω)		T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade	
ERJU6S (0805)	0.25	±1, ±2, ±5	0.1 to 0.2	(E24)	0 to +150	-55 to +155	Grade 0	
ERJU6Q (0805)	0.25	± 1, ±2, ±3	0.22 to 1	(E24)	0 10 +150	-55 10 + 155	Grade 0	

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

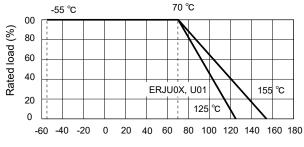
[For jumper]

Li di julliperj			
Part No.	Resistance	Rated current	Maximum overload current ^{*1}
ERJU0X	100 mQ or less	0.5 A	1 A
ERJU01		0.5 A	1 A
ERJS02,ERJU02		1 A	2 A
ERJS03,ERJU03		IA	27
ERJS06,ERJU06			
ERJS08,ERJU08	100 1112 01 1655		
ERJS14,ERJU14		2 A	4 A
ERJS12,ERJU12		27	7.7
ERJS1D,ERJU1D			
ERJS1T,ERJU1T			

^{*1:} Overload test current

Power derating curve

For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure below.



Ambient temperature (°C)

^{*2:} Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

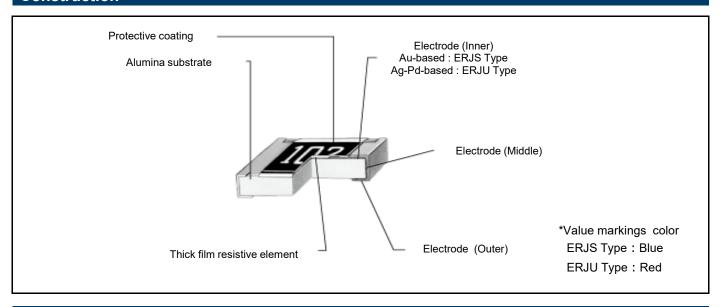
^{*3:} Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

[•] Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\(Power Rating \times Resistance Value. \)

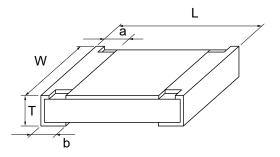
[·] Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

Anti-Sulfurated Thick Film Chip Resistors

Construction



Dimensions (not to scale)



Unit: mm

Davi Na	Dimensions								
Part No.	L	W	а	b	Т	(Reference) (g/1000 pcs)			
ERJU0X	0.40±0.02	0.20±0.02	0.10±0.03	0.10±0.03	0.13±0.02	0.04			
ERJU01	0.60±0.03	0.30±0.03	0.10±0.05	0.15±0.05	0.23±0.03	0.15			
ERJS02 ERJU02	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.10	0.35±0.05	0.8			
ERJS03 ERJU03	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2			
ERJS06 ERJU06	2.00±0.20 1.25±0.10		0.40±0.20	0.40±0.20	0.60±0.10	4			
ERJU6□	2.00±0.20	1.25±0.10	0.45±0.20	0.45±0.20	0.55±0.10	6			
ERJS08 ERJU08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10			
ERJS14 ERJU14	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16			
ERJS12 ERJU12	4.50±0.20 3.20±0.20 S1D 5.00±0.20 2.50±0.20		0.50±0.20	0.50±0.20	0.60±0.10	27			
ERJS1D ERJU1D			0.60±0.20	0.60±0.20	0.60±0.10	27			
ERJS1T ERJU1T	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45			

Anti-Sulfurated Thick Film Chip Resistors

Performance

• ERJS02 to ERJS1T, ERJU0X to ERJU1T series

Test item	Performance re	equirements ⊿R	Test conditions
rest item	Resistor type	Jumper type	rest conditions
Resistance	Within specified tolerance	100 mΩ or less	20 ℃
T. C. R.	Within Specified T. C. R.	200 mΩ or less	+25 °C / +155 °C (ERJU0X,U01 : +25 °C / +125 °C)
Overload	±2 %	100 mΩ or less	Rated voltage × 2.5, 5 s Jumper type : Max. overload current, 5 s
Resistance to soldering heat	±1 %	100 mΩ or less	270 ℃, 10 s
Rapid change of temperature	±1 %	100 mΩ or less	–55 ℃ (30min.)/+155 ℃ (ERJU0X,U01 : +125 ℃) (30min.), 100 cycles
High temperature exposure	±1 %	100 mΩ or less	+155 ℃ (ERJU0X,U01 : +125 ℃), 1000 h
Damp heat, Steady state	±1 %	100 mΩ or less	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	100 mΩ or less	60 ℃, 90 % to 95 %RH, Rated voltage (Jumper type : Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	100 mΩ or less	70 ℃, Rated voltage (Jumper type : Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h

• ERJU6S, U6Q series

Test Item	Performance requirements ⊿R	Test conditions				
Resistance	Within specified tolerance	20 ℃				
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃				
Overload	±1 %	Rated voltage × 2.5, 5 s				
Resistance to soldering heat	±1 %	270 ℃, 10 s				
Rapid change of temperature	±1 %	-55 ℃ (30 min.) / +125 ℃ (30min.), 100 cycles				
High temperature exposure	±1 %	+155 ℃, 1000 h				
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h				
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage 1.5 h ON / 0.5 h OFF cycle, 1000 h				
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h				

INDUSTRY

Anti-Sulfurated Thick Film Chip Resistors (Precision Type)



ERJ U□R type (Ag-Pd-based inner electrode type)

ERJ U2R, U3R, U6R series

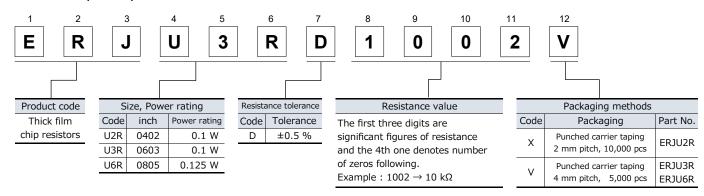
Features

- High resistance to sulfurization achieved by adopting an Ag-Pd-based inner electrode.
- ◆ High precision : Resistance tolerance : ±0.5 %, TCR : ±50 ×10⁻⁶/K
- High reliability : Metal glaze thick film resistive element and three layers of electrodes.
- Suitable for both reflow and flow soldering.
- Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note: Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.

ERJU2R, U3R, U6R series

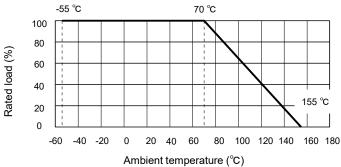


	Ratings								
	Part No. (inch size)	Power rating ^{*1} (70 ℃) (W)	Limiting element voltage ^{*2} (V)	Maxımum overload voltage ^{*3} (V)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC- Q200 Grade
	ERJU2R (0402)	0.1	50	100	±0.5	100 to 100 k (E24, E96)			
_	ERJU3R (0603)	0.1	75	150	±0.5	100 to 100 k (E24, E96)	±50	-55 to +155	Grade 0
_	ERJU6R (0805)	0.125	150	200	±0.5	100 to 100 k (E24, E96)			

- st 1 : Use it on the condition that the case temperature is below the upper category temperature.
- *2 : Rated continuous working voltage (RCWV) shall be determined from RCWV=√Power rating × Resistance value, or limiting element voltage listed above, whichever less.
- *3 : Overload test voltage (OTV) shall be determined from OTV = Specified magnification (refer to performance) × RCWV or maximum overload voltage listed above, whichever less.

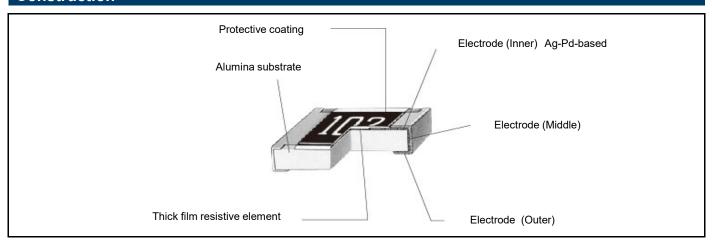
Power derating curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.

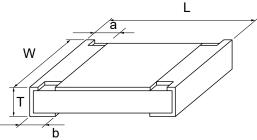


Anti-Sulfurated Thick Film Chip Resistors (Precsion Type)

Construction



Dimensions (not to scale)



Dimensions Mass (Weight) Part No. (Reference) W L b Τ (g/1000 pcs) 0.25±0.10 ERJU2R 1.00±0.05 0.50 ± 0.05 0.20±0.10 0.35±0.05 8.0 ERJU3R 1.60±0.15 0.80+0.15/-0.05 0.30±0.20 0.30±0.15 0.45±0.10 2 1.25±0.10 ERJU6R 2.00±0.20 0.40±0.20 0.40±0.20 0.60±0.10 4

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +155 ℃
Overload	±2 %	Rated voltage × 2.5, 5 s
Resistance to soldering heat	±1 %	270 ℃, 10 s
Rapid change of temperature	±1 %	–55 ℃ (30 min.) / +155 ℃ (30 min.), 100 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±2 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±2 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

INDUSTRY

Anti-Sulfurated Thick Film Chip Resistors (Anti-Surge Type)



ERJ UP type

ERJ UP3, UP6, UP8 series

Features

- High resistance to sulfurization achieved by adopting Anti-Sulfurated electrode material (Ag-Pd-based inner electrode) and structure
- ESD surge characteristics superior to standard metal film resistors
- High reliability : Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- High power 0.25 W: 0603 inch / 1608 mm size (ERJUP3)

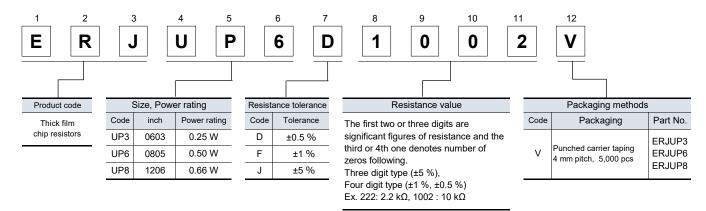
0.50 W: 0805 inch / 2012 mm size (ERJUP6) 0.66 W: 1206 inch / 3216 mm size (ERJUP8)

• Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C

- AEC-Q200 compliant
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note: Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



Ratings

Part No. (inch size)	Power rating*1 (70 ℃) (W)	Limiting element voltage*2 (V)	Maximum overload voltage*3 (V)	Resistance tolerance (%)	Resist ranç (Ω	ge	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJUP3	0.25	0.25 150		±0.5, ±1	10 to 1 M	(E24, E96)	±100		
(0603)	0.23	130	200	±5	1 to 1.5 M	(E24)	±200		
בם ייום:		0 400	600	±0.5, ±1	10 to 1 M	(E24, E96)	±100		
ERJUP6 (0805)	0.50			±5	1 to 3.3 M	(E24)	R<10 Ω : –100 to +600	-55 to +155	Grade 0
(0000)				10	1 to 3.3 ivi	(E2 4)	10 Ω≤R :±200	-55 10 +155	Grade 0
ED 11100		0.66 500		±0.5, ±1	10 to 1 M	(E24, E96)	±100		
(1206)	ERJUP8 0.66		1000	±5	1 to 10 M	(524)	R<10 Ω : –100 to +600		
(1200)				ΞЭ	1 10 10 101	(E24)	10 Ω≤R :±200		

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

^{*2:} Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

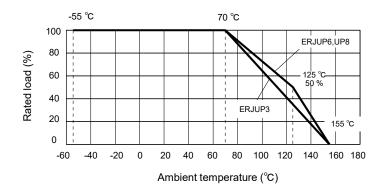
^{*3:} Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Anti-Sulfurated Thick Film Chip Resistors (Anti-Surge Type)

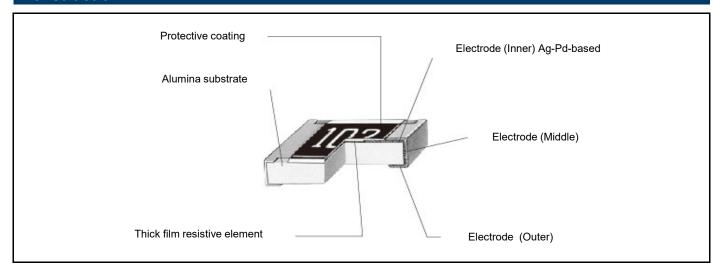
Ratings

Power derating curve

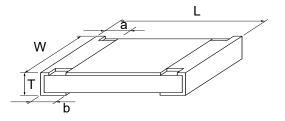
For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



Construction



Dimensions in mm (not to scale)

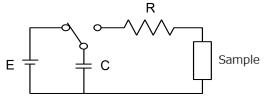


Unit : mm

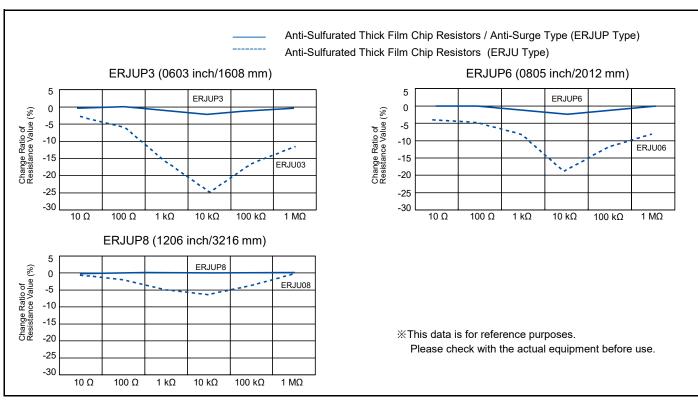
Part No.		Dimensions									
	L	W	а	b	b T (Refer						
ERJUP3	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.25±0.10	0.45±0.10	2					
ERJUP6	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4					
ERJUP8	3.20+0.05/-0.20	1.6+0.05/-0.15	0.40±0.20	0.50±0.20	0.60±0.10	10					

Anti-Sulfurated Thick Film Chip Resistors (Anti-Surge Type)

ESD Characteristic



R	R=0 Ω(\leq 1.5 kΩ) / 150 Ω($>$ 1.5 kΩ)
С	150 pF
E	±3 kV



Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +155 ℃
Overload	10.0/	ERJUP6 : Rated voltag x 1.77, 5 s
	±2 %	ERJUP3, ERJUP8 : Rated voltag x 2.0, 5 s
Resistance to soldering heat	D: ±0.5 % F, J: ±1 %	270 ℃, 10 s
Rapid change of temperature	±1 %	-55 ℃ (30 min.) / +155 ℃ (30 min.), 100 cycles
High temperature exposure	±1 %	+155 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

INDUSTRY





ERJ C type
ERJ C1 series

Features

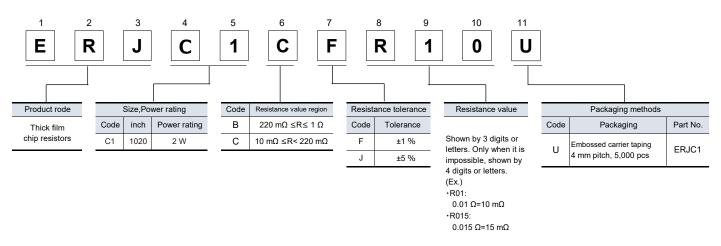
- High resistance to sulfurization achieved by adopting Anti-Sulfurated electrode material (Ag-Pd-based inner electrode) and structure (Covered electrode)
- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 compliant
- RoHS compliant

Recommended applications

- Motor control circuit of the industrial equipment
- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems
- Current sensing for power supply circuits in a variety of equipment
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note: Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



Ratings

Part No. (inch size)	Power rating ^{*1} (70 ℃) (W)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
ERJC1 (1020)	2	±1	10 m to 1 (E24)	$\begin{array}{c} 10 \text{ m}\Omega \leq R < 22 \text{ m}\Omega \ : 0 \text{ to } +350 \\ 22 \text{ m}\Omega \leq R < 47 \text{ m}\Omega \ : 0 \text{ to } +200 \\ 47 \text{ m}\Omega \leq R < 100 \text{ m}\Omega \ : 0 \text{ to } +150 \\ 100 \text{ m}\Omega \leq R \leq 1 \Omega \ : \pm 100 \end{array}$	–55 to +155	Grade 0
(1020)	±5	±5		10 mΩ ≤ R < 22 mΩ : 0 to +350 22 mΩ ≤ R < 100 mΩ : 0 to +200 100 mΩ ≤ R ≤ 1 Ω : ±200		

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

[·] Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\Power Rating x Resistance Value.

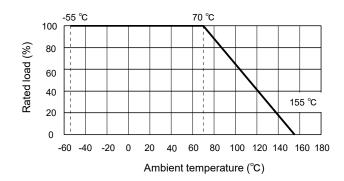
[·] Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW

Anti-Sulfurated High Power Chip Resistors (Wide Terminal Type)

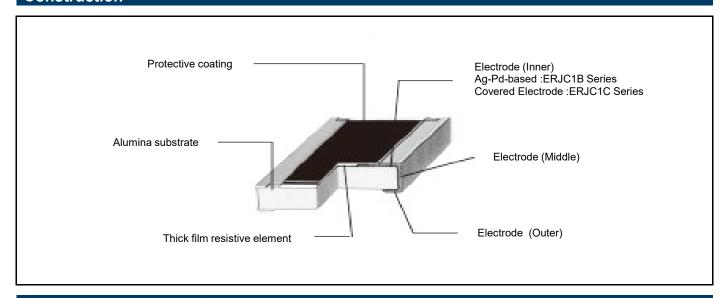
Ratings

Power derating curve

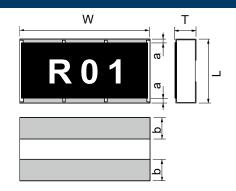
For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.



Construction



Dimensions (not to scale)

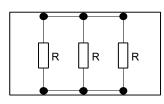


Unit : mm

Part No.		Dimensions									
	L	W	а	b	Т	(Reference) (g/1000 pcs)					
ERJC1B	2.50±0.20	5.00±0.20	0.35±0.20	0.90±0.20	0.55±0.20	27					
ERJC1C	2.50±0.20	J.00±0.20	0.60±0.20	0.90±0.20	0.55±0.20	27					

Circuit configuration

ERJC1 series



Anti-Sulfurated High Power Chip Resistors (Wide Terminal Type)

-55 °C (30 min.) / +125 °C (30 min.), 1000 cycles

+155 ℃, 1000 h

60 °C, 90 % to 95 %RH, 1000 h

60 ℃, 90 % to 95 %RH, Rated voltage,

1.5 h ON / 0.5 h OFF cycle, 1000 h

70 °C, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

Performance Performance Test Item Test conditions requirements ⊿R Within specified Resistance 20 ℃ tolerance Within specified T. C. R. +25 ℃ / +125 ℃ T. C. R. Overload ±2 % Rated voltage × 2.0, 5 s Resistance to ±1 % 270 ℃, 10 s soldering heat

Rapid change of

temperature High temperature

> exposure Damp heat,

Steady state

Load life in humidity

Endurance at 70 ℃

±2 %

±1 %

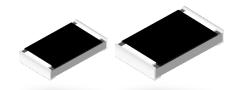
±1 %

±3 %

±3 %

INDUSTRY

High Temperature Thick Film Chip Resistor (Automotive Grade)



ERJH type

ERJ H2G, H2C, H2R, H3G series ERJ H3E, H3Q, H6G, HP6 series

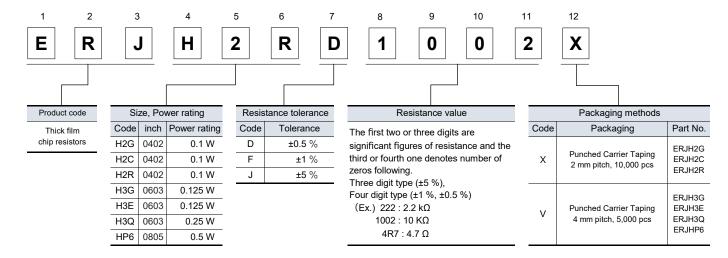
Features

- High reliability : Metal glaze thick film resistive element and high temperature of electrodes structure
- Achieve maximum category temperature 175 ℃ and rated category temperature 105 ℃
- Compatible with placement machines : Taping packaging available
- Suitable for both reflow and flow soldering
- Reference standard : IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

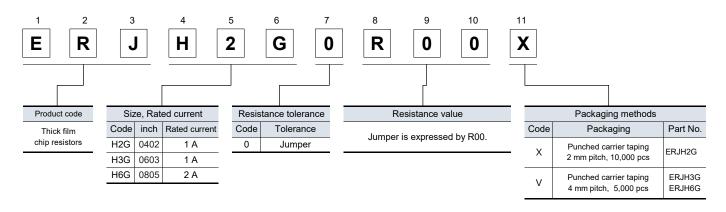
Explanation of part numbers

Note: Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.

ERJH2G, H2C, H2R, H3G, H3E, H3Q, HP6 series: ±0.5 %, ±1 %, ±5 %



ERJH2G, H3G, H6G series : Jumper



High Temperature Thick Film Chip Resistor (Automotive Grade)

Ratings

[For Resistor]

Power rating*1 (105 ℃) (W)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	Resistance tolerance (%)	Resistance range (Ω)		T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
0.1	50	100	±5	1 to 300 k	(E24)	R < 10Ω : -100 to $+600$ $10\Omega \le R$: ± 200		
0.1	50	100	±1	1 to 9.76	(E24,E96)	-100 to +600		
0.1	50	100	±0.5,±1	10 to 300 k	(E24,E96)	±100		Grade 0
0.125	75	150	±5	1 to 300 k	(E24)	R < 10Ω : -100 to +600 10Ω ≤ R : ±200	- 55 to +175	
0.125	75	150	±0.5,±1	10 to 300 k	(E24,E96)	±100		
0.25		_	±0.5,±1	1 to 9.76	(E24,E96)	+200		
0.20			±5	1 to 9.1	(E24)			
0.5	400	600	±0.5	10 to 300 k	(E24.E96)			
					(== :,== :)	*****		
0.5	400	600	±1	1 to 300 k	(E24,E96)			
0.5	400	600		4 += 200	(504)			
0.5	0.5 400 600	ΞЭ	1 10 300 K	(⊏24)				
	rating*1 (105 ℃) (W) 0.1 0.1 0.1 0.125	rating*1 element voltage*2 (V) 0.1 50 0.1 50 0.1 50 0.1 50 0.125 75 0.125 75 0.25 - 0.5 400 0.5 400	rating 1 element voltage 2 (V) 0.1 50 100 0.1 50 100 0.1 50 100 0.1 50 100 0.1 50 100 0.125 75 150 0.125 75 150 0.25 0.5 400 600	rating 1 element voltage 2 (V) Resistance tolerance (%) 0.1 50 100 ±5 0.1 50 100 ±1 0.1 50 100 ±0.5,±1 0.125 75 150 ±0.5,±1 0.25 ±0.5,±1 0.5 400 600 ±1	rating 1 (105 °C) (W) element voltage 2 (V) overload voltage 3 (V) Resistance tolerance (%) Resistance tolerance (%) Resistance tolerance (%) 0.1 50 100 ±5 1 to 300 k 0.1 50 100 ±1 1 to 9.76 0.1 50 100 ±0.5,±1 10 to 300 k 0.125 75 150 ±5 1 to 300 k 0.125 75 150 ±0.5,±1 10 to 300 k 0.25 - - ±0.5,±1 1 to 9.76 ±5 1 to 9.1 10 to 300 k 0.5 400 600 ±0.5 10 to 300 k	rating 1 (105 °C) (W) element voltage 2 (V) overload voltage 3 (V) Resistance tolerance (%) Resistance range (Ω) 0.1 50 100 ±5 1 to 300 k (E24) 0.1 50 100 ±1 1 to 9.76 (E24,E96) 0.1 50 100 ±0.5,±1 10 to 300 k (E24,E96) 0.125 75 150 ±5 1 to 300 k (E24,E96) 0.125 75 150 ±0.5,±1 10 to 300 k (E24,E96) 0.25 - - ±0.5,±1 1 to 9.76 (E24,E96) 0.5 400 600 ±0.5 10 to 300 k (E24,E96) 0.5 400 600 ±0.5 10 to 300 k (E24,E96)	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$

^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

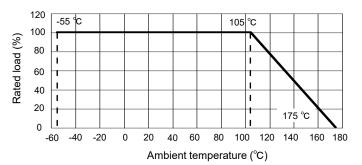
[For Jumper]

Part No. (inch size)	Resistance	Rated current	Maximum overload current ^{*1}
ERJH2G (0402)	50 mΩ or less	1 A	2 A
ERJH3G (0603)		1 A	2 A
ERJH6G (0805)		2 A	4 A

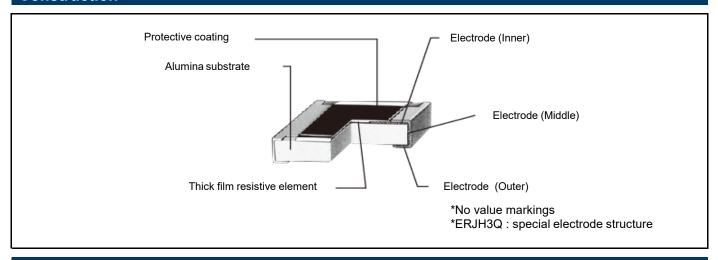
^{*1:} Overload test current

Power derating curve

For resistors operated in ambient temperatures above 105 $^{\circ}$ C, power rating shall be derated in accordance with the figure below.



Construction

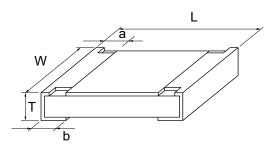


^{*2:} Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

^{*3:} Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

High Temperature Thick Film Chip Resistor (Automotive Grade)

Dimensions (not to scale)



Unit : mm

Part No.		Dimensions									
	L	W	а	b	Т	(Reference) (g/1000 pcs)					
ERJH2G	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8					
ERJH2C	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8					
ERJH2R	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	8.0					
ERJH3G	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2					
ERJH3E	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2					
ERJH3Q	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2					
ERJH6G	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4					
ERJHP6	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4					

Test item	Performance re	quirements ⊿R	Test conditions
rest item	Resistor type	Jumper type	- rest condutions
Resistance	Within specified tolerance	50 mΩ or less	20 ℃
T. C. R.	Within specified T. C. R.	50 mΩ or less	+25 ℃ / +175 ℃
Overload	±2 %	50 mΩ or less	ERJH2G, H2C, H2R, H3G, H3E, H3Q : Rated voltage× 2.5, 5 s ERJHP6: Rated voltage× 1.77, 5 s Jumper type: Max. overload current, 5 s
Resistance to soldering heat	±1 %	50 mΩ or less	270 ℃, 10 s
Rapid change of temperature	±1 %	50 mΩ or less	–55 °C (30 min.) / +175 °C (30 min.), 1000 cycles
High temperature exposure	±1 %	50 mΩ or less	+175 ℃, 1000 h
Damp heat, Steady state	±1 %	50 mΩ or less	85 ℃, 85 %RH, 1000 h
Load life in humidity	±3 %	50 mΩ or less	85 °C, 85 %RH, Rated voltage (Jumper type :Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 105 ℃	±3 %	50 mΩ or less	105 ℃, Rated voltage (Jumper type : Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h

INDUSTRY

Chip Resistors Array

EXB type

EXB 14V, 18V, 24V, 28V, N8V, 2HV, series

EXB 34V, V4V, 38V, V8V, S8V series



Features

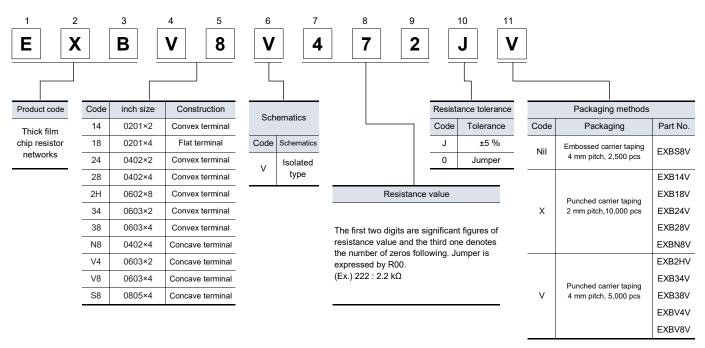
- High density
 - 2 resistors in 0.8 mm × 0.6 mm size / 0302 inch size : EXB14V
 - 4 resistors in 1.4 mm × 0.6 mm size / 0502 inch size : EXB18V
 - 2 resistors in 1.0 mm × 1.0 mm size / 0404 inch size : EXB24V
 - 4 resistors in 2.0 mm × 1.0 mm size / 0804 inch size : EXB28V, N8V
 - 8 resistors in 3.8 mm × 1.6 mm size / 1506 inch size : EXB2HV
 - 2 resistors in 1.6 mm × 1.6 mm size / 0606 inch size : EXB34V, V4V
 - 4 resistors in 3.2 mm × 1.6 mm size / 1206 inch size : EXB38V, V8V
 - 4 resistors in 5.1 mm × 2.2 mm size / 2009 inch size : EXBS8V
- Improvement of placement efficiency

Placement efficiency of Chip Resistor Array is two, four or eight times of the flat type chip resistor

- : IEC 60115-9, JIS C 5201-9, EIAJ RC-2129 Reference Standard
- AEC-Q200 compliant (EXB2, EXB3)
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note: Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



Ratings

[For Resistor]

Part No. (inch size)	Power rating (70 ℃) (W/element)	Limiting element voltage ^{*1} (V)	Maximum overload voltage ^{*2} (V)	Resistance tolerance (%)	Resistance range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (°C)	AEC-Q200 Grade
EXB14V (0201×2)	0.031	12.5	25	±5	10 to 1 M (E24)			
EXB18V (0201×4)	0.031 (0.1 W / package)	12.5	25	±5	10 to 1 M (E24)			-
EXB24V (0402×2)	0.063	50	100	±5	1 to 1 M (E24)			
EXB28V (0402×4)	0.063	50	100	±5	1 to 1 M (E24)			
EXB2HV (0602×8)	0.063 (0.25 W / package)	25	50	±5	10 to 1 M (E24)	R<10 Ω	-55 to +125	Grade 1
EXB34V (0603×2)	0.063	50	100	±5	1 to 1 M (E24)	: –200 to +600 10 Ω to 1 MΩ		
EXB38V (0603×4)	0.063	50	100	±5	1 to 1 M (E24)	: ±200		
EXBN8V (0402×4)	0.031	50	100	±5	10 to 1 M (E24)			
EXBV4V (0603×2)	0.063	50	100	±5	10 to 1 M (E24)	1		
EXBV8V (0603×4)	0.063	50	100	±5	10 to 1 M (E24)			-
EXBS8V (0805×4)	0.1	100	200	±5	10 to 1 M (E24)			

^{*1:} Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

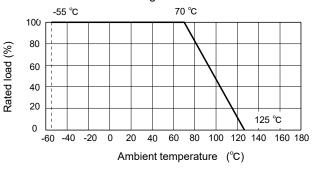
[For Jumper]

Part No.	Resistance	Rated current	Maximum overload current ^{*1}
EXB14V		0.5 A	1 A
EXB18V		0.5 A	1 A
EXB24V		1 A	2 A
EXB28V		1 A	2 A
EXB2HV		1 A	2 A
EXB34V	$50 \text{ m}\Omega$ or less	1 A	2 A
EXB38V		1 A	2 A
EXBN8V		1 A	2 A
EXBV4V		1 A	2 A
EXBV8V		1 A	2 A
EXBS8V		2 A	4 A

^{*1:} Overload test current

Power derating curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure below.

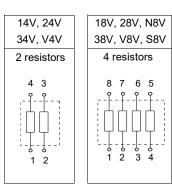


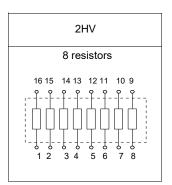
Construction (Example : Concave terminal)

Protective coating Alumina substrate Electrode (Outer) Thick film Electrode (Between) resistive element Electrode (Inner)

Schematics

● Isolated type



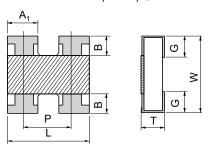


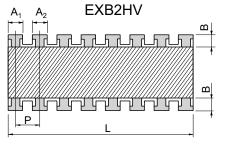
^{*2:} Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

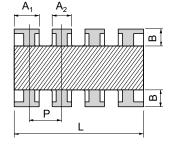
Dimensions (not to scale)

(1) Convex terminal type

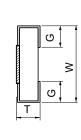
EXB14V, 24V, 34V







EXB28V, 38V



Unit:mm

Part No.	Dimensions								
(inch size)	L	W	Т	A ₁	A ₂	В	Р	G	(Reference) (g/1000 pcs)
EXB14V (0201×2)	0.80±0.10	0.60±0.10	0.35±0.10	0.35±0.10	_	0.15±0.10	(0.50)	0.15±0.10	0.5
EXB24V (0402×2)	1.00±0.10	1.00±0.10	0.35±0.10	0.40±0.10	_	0.18±0.10	(0.65)	0.25±0.10	1.2
EXB28V (0402×4)	2.00±0.10	1.00±0.10	0.35±0.10	0.45±0.10	0.35±0.10	0.20±0.10	(0.50)	0.25±0.10	2.0
EXB2HV (0602×8)	3.80±0.10	1.60±0.10	0.45±0.10	0.35±0.10	0.35±0.10	0.30±0.10	(0.50)	0.30±0.10	9.0
EXB34V (0603×2)	1.60±0.20	1.60±0.15	0.50±0.10	0.65±0.15	_	0.30±0.20	(0.80)	0.30±0.20	3.5
EXB38V (0603×4)	3.20±0.20	1.60±0.15	0.50±0.10	0.65±0.15	0.45±0.15	0.30±0.20	(0.80)	0.35±0.20	7.0

υļ

υļ

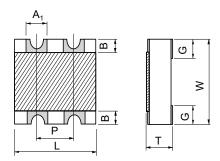
Т

≥

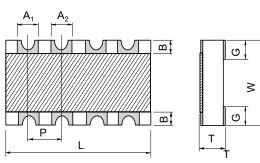
() Reference

(2) Concave terminal type

EXBV4V



EXBN8V, V8V, S8V



Unit : mm

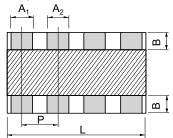
Part No.	Dimensions								Mass (Weight) (Reference)
(inch size)	L	W	Т	A ₁	A ₂	В	Р	G	(g/1000 pcs)
EXBN8V (0402×4)	2.00±0.10	1.00±0.10	0.45±0.10	0.30±0.10	0.30±0.10	0.20±0.15	(0.50)	0.30±0.15	3.0
EXBV4V (0603×2)	1.60 +0.20/-0.10	1.60 +0.20/-0.10	0.60±0.10	0.60±0.10	_	0.30±0.15	(0.80)	0.45±0.15	5.0
EXBV8V (0603×4)	3.20 +0.20/-0.10	1.60 +0.20/-0.10	0.60±0.10	0.60±0.10	0.60±0.10	0.30±0.15	(0.80)	0.45±0.15	10
EXBS8V (0805×4)	5.08 +0.20/-0.10	2.20 +0.20/-0.10	0.70±0.20	0.80±0.15	0.80±0.15	0.50±0.15	(1.27)	0.55±0.15	30

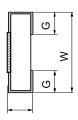
() Reference

Dimensions (not to scale)

(3) Flat terminal type







Unit : mm

Part No.		Dimensions							
(inch size)	L	W	Т	A_1	A_2	В	Р	G	(Reference) (g/1000 pcs)
EXB18V (0201×4)	1.40±0.10	0.60±0.10	0.35±0.10	0.20±0.10	0.20±0.10	0.10±0.10	(0.40)	0.20±0.10	1.0

() Reference

Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload	±2 %	Rated voltage x 2.5, 5 s Jumper type : Max. overload current, 5 s
Resistance to soldering heat	±1 %	270 ℃, 10 s
Rapid change of temperature	±1 %	-55 ℃ (30 min.) / +155 ℃ (30 min.), 100 cycles
High temperature exposure	±1 %	+125 ℃, 1000 h
Damp heat, Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
Load life in humidity	±3 %	60 ℃, 90 % to 95 %RH, Rated voltage (Jumper type : Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 ℃	±3 %	70 ℃, Rated voltage (Jumper type :Rated current), 1.5 h ON / 0.5 h OFF cycle, 1000 h

INDUSTRY

Anti-Sulfurated Chip Resistors Array

EXB type

EXB 14V, 18V, 24V, 28V, N8V, 2HV series

EXB 34V, V4V, 38V, V8V, S8V series



Features

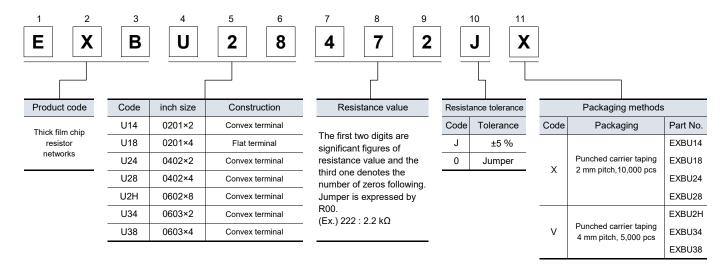
- High resistance to sulfurization achieved by adopting an Ag-Pd-based inner electrode
- High density
 - 2 resistors in 0.8 mm × 0.6 mm size / 0302 inch size : EXBU14
 - 4 resistors in 1.4 mm × 0.6 mm size / 0502 inch size : EXBU18
 - 2 resistors in 1.0 mm × 1.0 mm size / 0404 inch size : EXBU24
 - 4 resistors in 2.0 mm × 1.0 mm size / 0804 inch size : EXBU28
 - 8 resistors in 3.8 mm × 1.6 mm size / 1506 inch size : EXBU2H
 - 2 resistors in 1.6 mm × 1.6 mm size / 0606 inch size : EXBU34
 - 4 resistors in 3.2 mm × 1.6 mm size / 1206 inch size : EXBU38
- Improvement of placement efficiency

Placement efficiency of chip resistor array is two, four or eight times of the flat type chip resistor

- Reference standard : IEC 60115-9, JIS C 5201-9, EIAJ RC-2129
- AEC-Q200 compliant (EXBU2, EXBU3)
- RoHS compliant
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note: Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



Ratings

[For Resistor]

Part No. (inch size)	Power rating (70 ℃) (W/element)	Limiting element voltage ^{*1} (V)	Maximum overload voltage ^{*2} (V)	Resistance tolerance (%)	Resistar range (Ω)		T.C.R. (×10 ⁻⁶ /K)	Category temperature range (°C)	AEC-Q200 Grade
EXBU14 (0201×2)	0.031	12.5	25	±5	10 to 1 M	(E24)			
EXBU18 (0201×4)	0.031 (0.1 W / package)	12.5	25	±5	10 to 1 M	(E24)	R<10 Ω : –200 to +600 10 Ω to 1 MΩ : ±200	-55 to +125	-
EXBU24 (0402×2)	0.063	50	100	±5	1 to 1 M	(E24)			
EXBU28 (0402×4)	0.063	50	100	±5	1 to 1 M	(E24)			
EXBU2H (0602×8)	0.063 (0.25 W / package)	25	50	±5	10 to 1 M	(E24)			Grade 1
EXBU34 (0603×2)	0.063	50	100	±5	1 to 1 M	(E24)			
EXBU38 (0603×4)	0.063	50	100	±5	1 to 1 M	(E24)			

^{*1:} Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

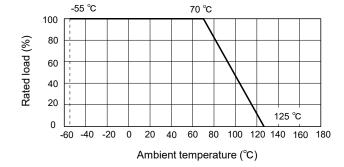
[For Jumper]

Part No.	Resistance	Rated current	Maximum overload current ^{*1}
EXBU24			
EXBU28			
EXBU2H	100 mΩ or less	1 A	2 A
EXBU34			
EXBU38			

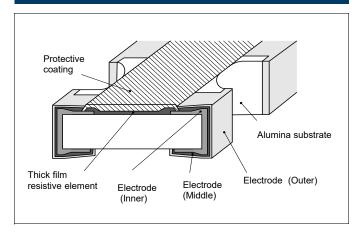
^{*1:} Overload test current

Power derating curve

For resistors operated in ambient temperatures above 70℃, power rating shall be derated in accordance with the figure below.

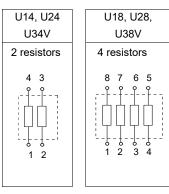


Construction



Schematics

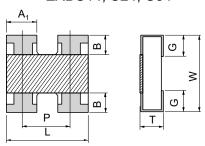
● Isolated type



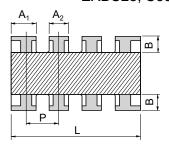
^{*2:} Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

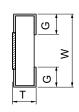
Dimensions (not to scale)

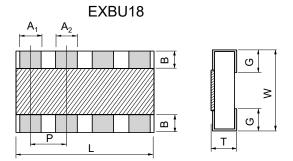
EXBU14, U24, U34

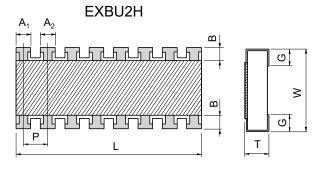


EXBU28, U38









Unit : mm

Part No.				Dime	nsions				Mass (Weight) (Reference)
(inch size)	L	W	Т	A ₁	A_2	В	Р	G	(g/1000 pcs)
EXBU14 (0201X2)	0.80±0.10	0.60±0.10	0.35±0.10	0.35±0.10	_	0.15±0.10	(0.50)	0.15±0.10	0.5
EXBU18 (0201×4)	1.40±0.10	0.60±0.10	0.35±0.10	0.20±0.10	0.20±0.10	0.10±0.10	(0.40)	0.20±0.10	1.0
EXBU24 (0402×2)	1.00±0.10	1.00±0.10	0.35±0.10	0.40±0.10	_	0.18±0.10	(0.65)	0.25±0.10	1.2
EXBU28 (0402×4)	2.00±0.10	1.00±0.10	0.35±0.10	0.45±0.10	0.35±0.10	0.20±0.10	(0.50)	0.25±0.10	2.0
EXBU2H (0602×8)	3.80±0.10	1.60±0.10	0.45±0.10	0.35±0.10	0.35±0.10	0.30±0.10	(0.50)	0.30±0.10	9.0
EXBU34 (0603×2)	1.60±0.20	1.60±0.15	0.50±0.10	0.65±0.15	_	0.30±0.20	(0.80)	0.30±0.20	3.5
EXBU38 (0603×4)	3.20±0.20	1.60±0.15	0.50±0.10	0.65±0.15	0.45±0.15	0.30±0.20	(0.80)	0.35±0.20	7.0

() Reference

Performance

1 enomiance		
Test Item	Performance	Test conditions
	requirements ⊿R	
Resistance	Within specified	20 ℃
	tolerance	
T. C. R.	Within Specified	+25 ℃ / +125 ℃
1. 0. 10.	T. C. R.	
Overload	±2 %	Rated voltage x 2.5, 5 s
Overload	12 /0	Jumper type: Max. overload current, 5 s
Resistance to	±1 %	270 ℃, 10 s
soldering heat	±1 70	270 C, 10 S
Rapid change of	±1 %	FF %C (20 main) / 142F %C (20 main) 400 avalor
temperature	±1 70	-55 $^{\circ}$ C (30 min.) / +125 $^{\circ}$ C (30 min.), 100 cycles
High temperature	±1 %	1405 °C 4000 h
exposure	±1 70	+125 ℃, 1000 h
Damp heat,	14.0/	00 %C 00 0/ +- 05 0/ DLL 4000 I
Steady state	±1 %	60 ℃, 90 % to 95 %RH, 1000 h
-		60 ℃, 90 % to 95 %RH, Rated voltage
Load life in humidity	±3 %	(Jumper type : Rated current),
·		1.5 h ON / 0.5 h OFF cycle, 1000 h
		70℃, Rated voltage (Jumper type : Rated current),
Endurance at 70℃	±3 %	1.5 h ON / 0.5 h OFF cycle, 1000 h
	1	1.0 11 014 / 0.0 11 011 01010, 1000 11

Panasonic

INDUSTRY

Chip Resistors Networks

EXB type

EXB D, E, A, Q series



Features

- High density placing for digital signal circuits
 - ·Bussed 8 or 15 resistors for pull up/down circuits

EXBD : 3.2 mm × 1.6 mm × 0.55 mm, 0.635 mm pitch EXBE : 4.0 mm × 2.1 mm × 0.55 mm, 0.8 mm pitch EXBA : 6.4 mm × 3.1 mm × 0.55 mm, 1.27 mm pitch EXBQ : 3.8 mm × 1.6 mm × 0.45 mm, 0.5 mm pitch

- Available direct placing on the bus line by means of half pitch spacing without through-holes on PWB ("High density placing" is shown below)
- High speed mounting using conventional placing machine

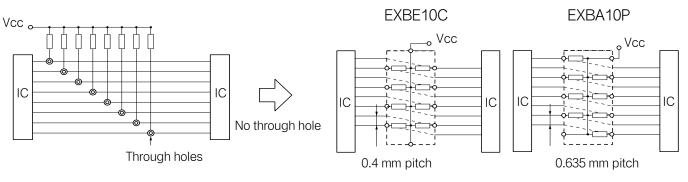
Reference Standard : IEC 60115-9, JIS C 5201-9, EIAJ RC-2130

RoHS compliant

【 High density placing 】

Pull up resistors

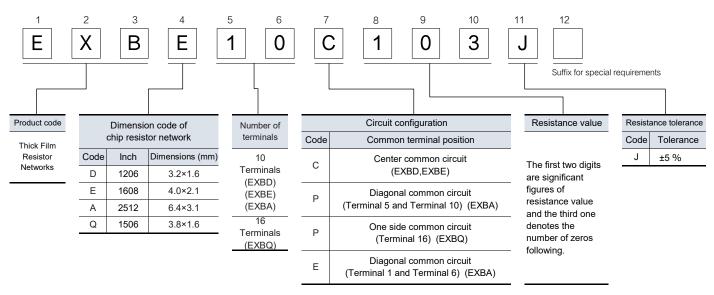
Direct placement on the bus line



■ As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note: Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.



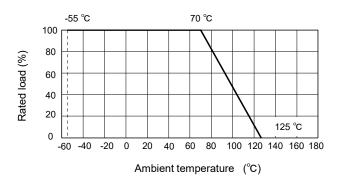
Ratings

Part No. (inch size)	Resistance range (Ω)	Resistance tolerance (%)	Number of terminals	Number of resistors	Power rating ^{*1} (70 °C) (W/element)	Limiting element voltage ^{*2} (V)	Maximum overload voltage ^{*3} (V)	T.C.R. (×10 ⁻⁶ /K)	Category temperature range (℃)	AEC-Q200 Grade
EXBD (1206)					0.05 / element	25	50	±200		
EXBE (1608)	47 to 1 M (E12)	±5	10 terminals	8 element	0.063 / element	25	50	±200	-55 to +125	
EXBA (2512)		13			0.063 / element	50	100	±200	-55 to +125	-
EXBQ (1506)	100 to 470 k (E6)		16 terminals	15 element	0.025 / element	25	50	±200		

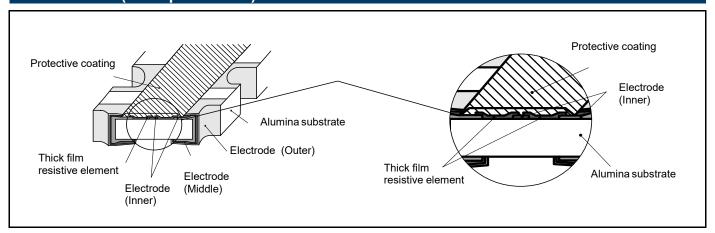
^{*1:} Use it on the condition that the case temperature is below the upper category temperature.

Power derating curve

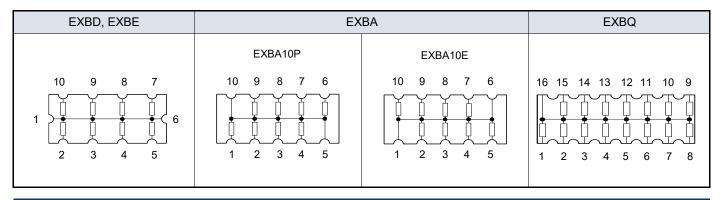
For resistors operated in ambient temperatures above 70 ℃, power rating shall be derated in accordance with the figure on the right.



Construction (Example: EXBD)



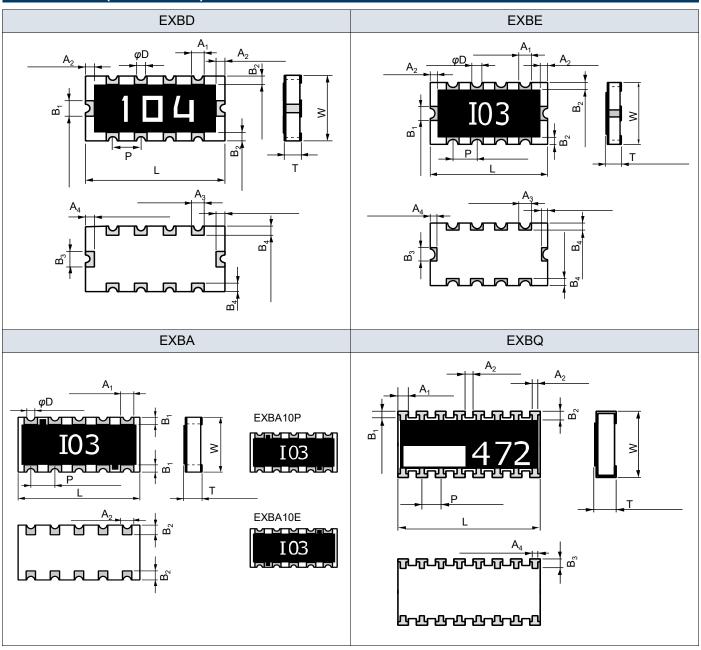
Circuit configuration



^{*2:} Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

^{*3:} Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Dimensions (not to scale)



1.1 14	
Unit	 m

								Unit : mm
Part No.				Dimensions				Mass (Weight) (Reference)
i ait ivo.	L	W	T	A ₁	A_2	B ₁	B ₂	(g/1000 pcs)
	3.20±0.15	1.60±0.15	0.55±0.10	0.33±0.15	0.2±0.1	0.40±0.15	0.2±0.1	
EXBD	A_3	A_4	B ₃	B ₄	Р	ø D		10
	0.3±0.1	0.25±0.10	0.40±0.15	0.35±0.15	0.635±0.10	0.2±0.1		
				Dimensions				Mass (Weight)
Part No.	L	W	Т	A ₁	A_2	B ₁	B ₂	(Reference) (g/1000 pcs)
	4.0±0.2	2.1±0.2	0.55±0.10	0.5±0.2	0.3±0.2	0.5±0.2	0.25±0.20	
EXBE	A_3	A_4	B ₃	B ₄	Р	øD		16
	0.4±0.2	0.35±0.20	0.5±0.2	0.4±0.2	0.8±0.1	0.3+0.1/-0.2		
David Na				Dimensions				Mass (Weight) (Reference)
Part No.	L	W	Т	A ₁	B ₁	A ₂	B ₂	(g/1000 pcs)
	6.4±0.2	3.1±0.2	0.55±0.10	0.7±0.2	0.3±0.2	0.5±0.2	0.5±0.20	
EXBA	Р	øD						40
	1.27±0.10	0.3+0.1/-0.2						
Dort No				Dimensions				Mass (Weight)
Part No.	L	W	T	A ₁	A ₂	A_3	B ₁	(Reference) (g/1000 pcs)
	3.8±0.2	1.6±0.2	0.45±0.10	0.3±0.1	0.2±0.1	0.15+0.15/-0.05	0.15+0.15/-0.05	
l		۸	B_3	Р				9
EXBQ	B_2	A_4	D ₃					9

Chip Resistors Networks

Performance

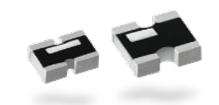
Test Item	Performance requirements ⊿R	Test conditions
Resistance	Within specified tolerance	20 ℃
T. C. R.	Within specified T. C. R.	+25 ℃ / +125 ℃
Overload	±3 %	Rated voltage x 2.5, 5 s
Resistance to soldering heat	±1 %	260 ℃ ±5 ℃, 5 s ±1 s
Rapid change of temperature	±2 %	-55 °C (30 min.) / +125 °C (30 min.), 5 cycles
High temperature exposure	±3 %	+125 ℃, 100 h
Load life in humidity	±3 %	60 ℃±2 ℃, 90 % to 95 %RH, Rated power × 0.1, 1.5 h ON / 0.5 h OFF cycle, 500 h
Endurance at 70 ℃	±5 %	70 ℃±2 ℃, Rated voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

INDUSTRY

Chip Attenuator

EXB type

EXB 14AT, 24AT series



Features

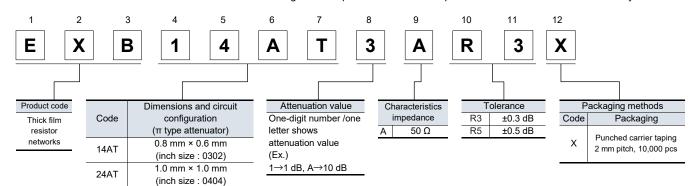
- Unbalanced π type attenuator circuit in one chip EXB14AT (0.8 mm×0.6 mm), EXB24AT (1.0 mm×1.0 mm)
- Reduced mounting area
 - EXB14AT: About 60 % smaller than the area of an attenuator circuit consisting of three 0603 chip resistors, almost equal to the area of three 0402 chip resistors
 - EXB24AT: About 50 % smaller than the area of an attenuator circuit consisting of three 1005 chip resistors, almost equal to the area of three 0603 chip resistors
- Mounting cost reduction : (Only 1 chip placed as compared to 3)
- Attenuation: 1 dB to 10 dB
- RoHS compliant

Recommended applications

- Attenuation / level control / impedance matching of high frequency (communication signalling equipment cellular phones(GSM, CDMA, PDC, etc.), PHS, PDAs)
 - As for packaging methods, land pattern, soldering conditions and safety precautions, please see data files.

Explanation of part numbers

Note: Please check the "Ratings" for the presence/absence of part numbers for combinations of the symbols below.

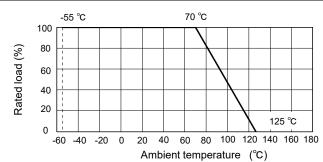


Ratings Part No. EXB14AT, EXB24AT Attenuation value 1 dB, 2 dB, 3 dB, 4 dB, 5 dB, 6 dB, 10 dB* 1 dB, 2 dB, 3 dB, 4 dB, 5dB: ±0.3 dB Attenuation value tolerance 6 dB, 10 dB: ±0.5 dB Characteristic impedance 50 Ω 0.04 W / package Power rating at 70 ℃ DC to 3.0 GHz Frequency range VSWR (Voltage standing wave ratio) 1.3 max. Number of resistors 3 resistors Number of terminals 4 terminals Category temperature range –55 ℃ to +125 ℃

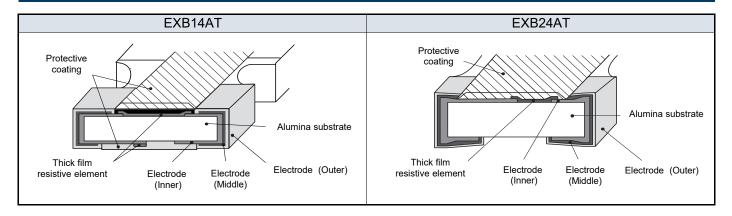
* Please inquire about the other Attenuator value

Power derating curve

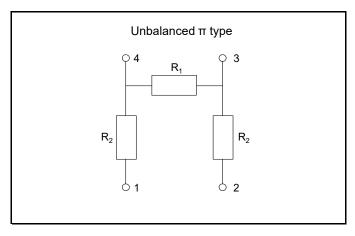
For resistors operated in ambient temperatures above 70 ℃, power rating shall be derated in accordance with the figure on the right.



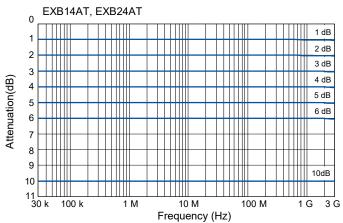
Construction



Circuit configuration

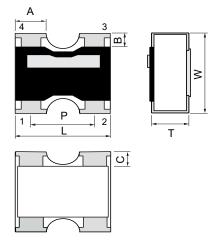


Attenuation-frequency characteristics



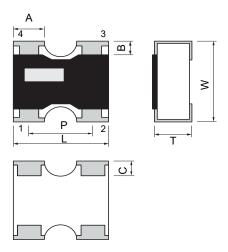
Dimensions (not to scale)





< Marking Configuration> The bar marking for recognizing terminal direction is located on the side of terminal 3, 4.

EXB24AT



< Marking Configuration> The bar marking for recognizing terminal direction is located on the side of terminal 4.

								Unit: mm
				Dimensions				Mass (Weight)
Part No.		1.00	_		_		D ((Reference)
	L	W	l l	A	В	C	P (typical value)	(g/1000 pcs)
EXB14AT	0.80±0.10	0.60±0.10	0.35±0.10	0.35±0.10	0.15±0.10	0.15±0.10	0.50	0.7
EXB24AT	1.00±0.10	1.00±0.10	0.35±0.10	0.40±0.10	0.15±0.10	0.25±0.10	0.65	1.1

Surfac	ce mount resistors series	3		Packaging (Standard	d quantity : pcs/reel)	
		0:	Pressed	Punched	Punched	Embossed
Products	Part No.	Size	carrier taping	carrier taping	carrier taping	carrier taping
		(mm) (inch)	(2 mm pitch)	(2 mm pitch)	(4 mm pitch)	(4 mm pitch)
	ERJXGN	0402 (01005)	20,000*1	_	_	40,000*2
	ERJ1GN	0603 (0201)	15,000	_	_	
	ERJ2GE	1005 (0402)	_	10,000	_	_
	ERJ3GE	1608 (0603)	_	_	5,000	_
Thick film	ERJ6GE	2012 (0805)	_	_	5,000	_
chip resistors	ERJ8GE	3216 (1206)		_	5,000	_
-	ERJ14	3225 (1210)			— — — — — — — — — — — — — — — — — — —	5,000
	ERJ12	4532 (1812)				5,000
	ERJ12Z	5025 (2010)	<u> </u>	_		5,000
	ERJ1T	6432 (2512)				4,000
	ERJXGN	0402 (01005)			<u> </u>	
	ERJ1GN/1RH	0603 (0201)	20,000 ^{*1} 15,000	_	<u> </u>	40,000 ^{*2}
	ERJ2RC/2RH/2RK	1005 (0402)		10,000	<u> </u>	_
		. ,	_	10,000		_
Precision	ERJ3RB/3RE/3EK ERJ6RB/6RE/6EN	1608 (0603)	_	_	5,000	_
thick film		2012 (0805)	_	_	5,000	_
chip resistors	ERJ8EN	3216 (1206)	_	_	5,000	_
	ERJ14N	3225 (1210)	-	-	-	5,000
	ERJ12N	4532 (1812)	_	_	_	5,000
	ERJ12S	5025 (2010)	_	_	_	5,000
	ERJ1TN	6432 (2512)	_	_		4,000
Market Closs	ERA1A	0603 (0201)	15,000	_	_	_
Metal film (Thin film)	ERA2A/2V	1005 (0402)	_	10,000	_	_
chip resistors,	ERA3A/3V/3K	1608 (0603)	_	_	5,000	_
High reliability type	ERA6A/6V/6K	2012 (0805)	_	_	5,000	_
, , , ,	ERA8A/8V/8K/8P	3216 (1206)	_		5,000	_
	ERJ2LW/2BW	1005 (0402)	10,000		_	_
	ERJ2BS/2BQ	1005 (0402)		10,000		_
	ERJ3L/3B/3R/L03	1608 (0603)	_	_	5,000	_
Thick film	ERJ6L/6B/6C ERJ6D/6R/L06	2012 (0805)	_	_	5,000	_
chip resistors/	ERJ8B/8C/8R/L08	3216 (1206)			5,000	
Low resistance type	ERJ14B/14R/L14	3225 (1210)				5,000
,,	ERJ12R/L12	4532 (1812)				5,000
	ERJ12Z/L1D	5025 (2010)				5,000
	ERJ1TR	6432 (2512)		_		4,000
	ERJL1W	6432 (2512)				3,000
	ERJMP2	3216 (1206)		_	_	3,000
	ERJMP3	5025 (2010)	<u>—</u>	_	<u> </u>	3,000
		6432 (2512)	<u>—</u>	_	<u> </u>	·
Current sensing	ERJMP4 ERJMS4	, ,	_	_	_	2,000
resistors,	ERJIVI54	6432 (2512)	_	_	<u> </u>	2,000
Metal plate type	ERJMS6	6468 (2526)	_	_	_	1,000 (8mm Pitch)
	ERJMB1	2550 (1020)	_	_	_	3,000
	ERJM1W	6432 (2512)	_	_	_	3,000
Current sensing resistors, Metal foil type	ERJMFBA	1005 (0402)	_	10,000	_	_
	ERJA1	3264 (1225)	_	_	_	4,000
High power chip resistors/	ERJB1/ERJC1*3 ERJD1*4	2550 (1020)	_	_	_	5,000
Wide terminal type	ERJB2/ERJD2*4	1632 (0612)	_	_	5,000	_
	ERJB3	1220 (0508)	_	_	5,000	_
				1		l .

^{*1:} W8P2 : Width 8 mm, Pitch 2 mm,

^{*2:} W4P1 : Width 4 mm, Pitch 1 mm

^{*3:} Anti-Sulfurated High power chip resistors / Wide terminal type

^{*4:} Low TCR High power chip Resistors / Wide terminal type

Surface	e mount resistors serie	es		Packaging (Standar	· · · · · · · · · · · · · · · · · · ·	
		Size	Pressed	Punched	Punched	Embossed
Products	Part No.	(mm) (inch)	carrier taping	carrier taping	carrier taping	carrier taping
		, , , ,	(2 mm pitch)	(2 mm pitch)	(4 mm pitch)	(4 mm pitch)
High precision thick	ERJPB3	1608 (0603)	_	_	5,000	_
film chip resistors	ERJPB6	2012 (0805)	_	_	5,000	_
	ERJPA2	1005 (0402)	_	10,000	_	_
North Common This of files	ERJP03/PA3	1608 (0603)	_	_	5,000	_
Anti-Surge Thick film chip resistors	ERJP06	2012 (0805)	_	_	5,000	_
Criip resistors	ERJP08/PM8	3216 (1206)	_	_	5,000	_
	ERJP14	3225 (1210)	_	_	_	5,000
	ERJT06	2012 (0805)	_	_	5,000	_
Anti-Pulse Thick	ERJT08	3216 (1206)	_	_	5,000	_
film chip resistors	ERJT14	3225 (1210)	_	_	_	5,000
	ERJU0X	0402 (01005)	20,000	_	_	
	ERJU01	0603 (0201)	15,000	_	_	_
	ERJS02/U02	1005 (0402)		10,000		_
	ERJS03/U03	1608 (0603)			5,000	
	ERJS06/U06	1000 (0000)			0,000	
Anti-Sulfurated Thick film	ERJU6S/U6Q	2012 (0805)	_	_	5,000	
chip resistors	ERJS08/U08	3216 (1206)	_		5,000	_
	ERJS14/U14	3225 (1210)	_	_	_	5,000
	ERJS12/U12	4532 (1812)	_	_	_	5,000
	ERJS1D/U1D	5025 (2010)	_	_	_	5,000
	ERJS1T/U1T	6432 (2512)	_	_	_	4,000
Anti-Sulfurated	ERJU2R	1005 (0402)	_	10,000	_	_
Thick film chip	ERJU3R	1608 (0603)		, 	5,000	
resistors /		, ,			· · · · · · · · · · · · · · · · · · ·	
Precision type	ERJU6R	2012 (0805)	_	_	5,000	_
Anti-Sulfurated	ERJUP3	1608 (0603)	_	_	5,000	_
Thick film chip resistors /	ERJUP6	2012 (0805)	_	_	5,000	_
Anti-Surge type	ERJUP8	3216 (1206)	_	_	5,000	_
	ERJH2G/2C/2R	1005 (0402)	_	10,000	_	_
High temperature thick	ERJH3G/3E/3Q	1608 (0603)	_	_	5,000	_
film chip resistor	ERJH6G/HP6	2012 (0805)	_	_	5,000	_
	EXB14V	0806 (0302)	_	10,000	_	_
	EXB24V	1010 (0404)	_	10,000	_	_
	EXB34V	1616 (0606)		_	5,000	
	EXBV4V	1616 (0606)			5,000	
	EXB18V	1406 (0502)	<u> </u>	10,000	· · · · · · · · · · · · · · · · · · ·	
Chip resistor	EXB28V	2010 (0804)		10,000	_	<u> </u>
array	EXBN8V	2010 (0804)	_		_	
			_	10,000	<u> </u>	_
	EXB38V	3216 (1206)		_	5,000	
	EXBV8V	3216 (1206)		_	5,000	
	EXBS8V	5022 (2009)	_	_		2,500
	EXB2HV	3816 (1506)	_	_	5,000	_
_	EXBU14	0806 (0302)	_	10,000	_	_
	EXBU18	1406 (0502)	_	10,000	_	_
Anti-Sulfurated	EXBU24	1010 (0404)	_	10,000	_	_
chip resistor array	EXBU34	1616 (0606)	_	_	5,000	
p : : - : - : - : - : - : - : - : -	EXBU28	2010 (0804)	_	10,000	_	_
	EXBU38	3216 (1206)	_	_	5,000	_
	EXBU2H	3816 (1506)	_	_	5,000	_
	EXBD	3216 (1206)	_	_	5,000	_
	EXBE	4021 (1608)	_	_	<u> </u>	4,000
hip resistor networks	EXBA	6431 (2512)	_	_	_	4,000
	EXBQ	3816 (1506)	_	_	5,000	
	EXB14AT	0806 (0302)	_	10,000		
Chip attenuator	EXB24AT	1010 (0404)		10,000		

øD₁ (Only Emboss)



Carrier tape Pressed Punched Embossed carrier carrier carrier ϕD_0 Щ ≥ 1 <u>m</u> 0 Т Т A (2 mm pitch)

Pressed	Pressed carrier taping (2 mm Pitch)													
● Chip resistors / Precision chip / Metal film(Thin film)chip / Low resistance / Anti-Sulfurated														
Part No.	Size (inch)	Α	В	W	F	Е	P ₁	P ₂	P ₀	ϕD_0	Т			
ERJXGN ERJU0X	0402 (01005)	0.24±0.03	0.45±0.03								0.31±0.05			
ERJ1GN ERJ1R□ ERJU01 ERA1A	0603 (0201)	0.38±0.05	0.68±0.05	8.00±0.20	3.50±0.05	1.75±0.10	2.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	0.42±0.05			
ERJ2LW	1005 (0402)	0.68±0.10	1.20±0.10								0.60±0.05			
ERJ2BW	1111 (0.02)	0.67±0.10	1.17±0.10								0.61±0.05			

Punched	Punched carrier taping (2 mm Pitch)												
Chip resistors / Precision chip / Thin film chip / Low resistance / Anti-Surge / Anti-Sulfur / High temperature / Metal foil type													
Part No.	Size (inch)	Α	В	W	F	Е	P ₁	P ₂	P ₀	øD ₀	Т		
ERJ2 ERJPA2 ERJ ERJ ERJ ERJ	1005 (0402)	0.67±0.05	1.17±0.05	8.00±0.20	3.50±0.05	1.75±0.10	2.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	0.52±0.05		
ERJMFBA											0.60±0.05		

 Chip resisto 	Chip resistor array / Anti-Sulfurated chip resistor Aarray / Chip attenuator											
Part No.	Size (inch)	Α	В	W	F	Е	P ₁	P ₂	P ₀	ϕD_0	Т	
EXB14V	0806	0.70	0.95									
EXB14AT	(0302)	+0.10/-0.05	+0.05/-0.10									
EXB18V	1406 (0502)		1.60±0.10									
EXB24V EXBU24 EXB24AT	1010 (0404)	1.20±0.10	1.20±0.10	8.00±0.20	3.50±0.05	1.75±0.10	2.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	0.52±0.05	
EXB28V EXBU28 EXBN8V	2010 (0804)		2.20±0.10									

Punched	d carrier t	taping (4 mm P	itch)							
● Chip resisto	● Chip resistors / Precision chip / Metal film(Thin film)chip / Low resistance / High power / High precision / Anti-Surge /										
Anti-Pulse / Anti-Sulfurated / High temperature											Unit : mm
Part No.	Size (inch)	Α	В	W	F	E	P ₁	P ₂	P ₀	ϕD_0	Т
ERJ3 □ ERJ3LW(10mΩ) ERJ3BW ERJ□3 ERJ□3 □ ERA3□ ERJ3LW(5mΩ)	1608 (0603)	1.10±0.10	1.90±0.10								0.70±0.05
ERJ6 ERJ 6 ERJ 6 ERJ 6 ERJ6 ERJ6	2012 (0805) 1220 (0508)	1.65±0.15	2.50±0.20	8.00±0.20	3.50±0.05	1.75±0.10	4.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	0.84±0.05
FKJ0RM	2012										

2012

(0805)

3216

(1206)

1632

(0612)

ERJ6LW

ERJ6CW ERJ8□ ERJ8□W

ERJ□□8

ERA8□ ERJB2

ERJD2

1.55±0.15

2.00±0.15

2.30±0.20

3.60±0.20

0.94±0.05

0.84±0.05

•	Chin resistor array	/ / Anti-Sulfurated chin resisto	or array / Chip resistor networks
•	Chip resistor arra	/ / Anti-Sunurated Chip resist	n array / Crip resistor networks

Chip resistor array / Anti-Sulfurated chip resistor array / Chip resistor networks											Unit : mm
Part No.	Size (inch)	Α	В	W	F	Е	P ₁	P ₂	P ₀	ϕD_0	T
EXB34V EXBU34	1616 (0606)		1.95±0.20								
EXB38V EXBU38	3216 (1206)		3.60±0.20								0.70±0.05
EXB2HV EXBU2H	3816 (1506)	1.95±0.15	4.10±0.15	8.00±0.20	3.50±0.05	1.75±0.10	4.00±0.10	2.00±0.05	4.00±0.10	1.50	
EXBV4V	1616 (0606)		1.95±0.20							+0.10/0	0.84±0.05
EXBV8V	3216 (1206)		3.60±0.20								0.04±0.05
EXBD	3216 (1206)	2.00±0.20	3.60±0.20								0.84±0.10
EXBQ	3816 (1506)	1.90±0.20	4.10±0.20	1							0.64±0.05

Embossed carrier taping (1 mm Pitch)

(:h	ın	resis	tors

Only resiste	• Only resistors											
Part No.	Size (inch)	Α	В	W	F	Е	P ₁	P_2	P ₀	ϕD_0	Т	
ERJXGN	0402 (01005)	0.25±0.05	0.45±0.05	4.00±0.20	1.80±0.05	0.90±0.10	1.00±0.10	1.00±0.10	2.00±0.10	0.80±0.10	0.5 max.	

Embossed carrier taping (4 mm Pitch)

Chip resistors / Precision chip / Low resistance / High power / Anti-Surge / Anti-Pulse / Anti-Sulfurated

Unit: mm												
Part No.	Size (inch)	Α	В	W	F	E	P ₁	P_2	P ₀	$ \emptyset D_0 $	Т	øD₁
ERJ14□ ERJ□14	3225 (1210)	2.80±0.20	3.50±0.20	8.00±0.30	3.50±0.05							1.00 +0.10/0
ERJ12□ ERJ□12	4532 (1812)	3.50±0.20	4.80±0.20									
ERJ12Z ERJ12S ERJ□1D	5025 (2010)	- 2.80±0.20	5.30±0.20			1.75	4.00	2.00	4.00	1.50	1.00±0.10	
ERJB1 ERJC1 ERJD1	2550 (1020)	2.0010.20	3.3010.20	12.00 ±0.30	5.50±0.20	±0.10	±0.10	±0.05	±0.10	+0.10/0		15 min.
ERJ1T□ ERJ□1T ERJL1W	6432 (2512)	3.60±0.20	6.90±0.20								1.60±0.10	
ERJA1	3264 (1225)	3.50±0.20	6.80±0.20								1.10±0.20	

Current sensing resistors, Metal plate type

Init	mm
Ollic	

• Garront Go	nomig roototoro,	motal plate	typo									Unit : mm
Part No.	Size (inch)	Α	В	W	F	Е	P ₁	P ₂	P ₀	ϕD_0	Т	øD₁
ERJMP2 (1 mΩ)	3216 (1206)										1.55±0.20	_
ERJMP2 (2 mΩ)	3216 (1206)	1.90±0.20	3.50±0.20	8.00±0.30	3.50±0.10						1.40±0.20	_
ERJMP2 (3 to 50 mΩ)	3216 (1206)										1.10±0.20	_
ERJMP3 (1 to 2 mΩ)	5025 (2010)			40.00							1.55±0.20	_
ERJMP3 (3 to 50 mΩ)	5025 (2010)	2.90±0.20	5.40±0.20	12.00 ±0.30	5.50±0.10	1.75 ±0.10	4.00 ±0.10	2.00 ±0.05	4.00 ±0.10	1.50 +0.10/0	1.15±0.20	_
ERJMB1	2550 (1020)										1.55±0.20	_
ERJMP4 (1 to 2 mΩ)	6432 (2512)										1.60±0.20	1.5 min.
ERJMP4 (3 to 50 mΩ)	6432 (2512)	3.50±0.20	6.90±0.20	12.00 ±0.30	5.50±0.10						1.20±0.20	_
ERJMS4	6432 (2512)	1			1.60±0.20	1.5 min.						
ERJM1W	6432 (2512)										1.80±0.20	1.5 min.

• Chip resistor array / Chip resistor networks

Unit	:	mm	

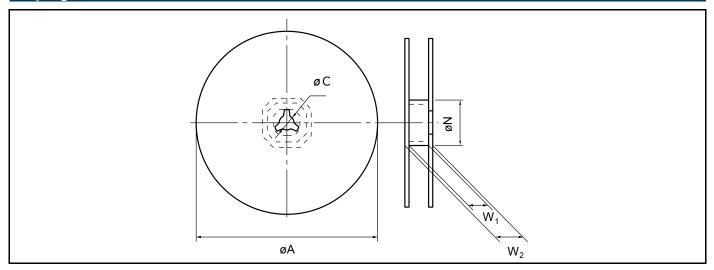
Part No.	Size (inch)	Α	В	W	F	Е	P ₁	P ₂	P_0	øD ₀	Т	øD ₁
EXBS8V	5022 (2009)	2.80±0.20	5.70±0.20			4.75	4.00	0.00	4.00	4.50	1.6 max.	
EXBE	4021 (1608)	2.50±0.20	4.40±0.20	12.00±0.30	5.50±0.20	1.75 ±0.10	4.00 ±0.10	2.00 ±0.05	4.00 ±0.10	1.50 +0.10/0	1.10±0.20	1.5 min.
EXBA	6431 (2512)	3.50±0.20	6.80±0.20						_5.10	3.10/0	1.1010.20	

Embossed carrier taping (8 mm Pitch)

● Current sensing resistors, Metal plate type												
Part No.	Size (inch)	Α	В	W	F	Е	P ₁	P ₂	P ₀	øD ₀	Т	øD ₁
ERJMS6	6468 (2526)	6.90±0.20	7.50±0.20	12.00	5.50±0.05	1.75	8.00	2.00	4.00	1.50	2.45±0.20	1.5 min.



Taping reel



Unit: mm

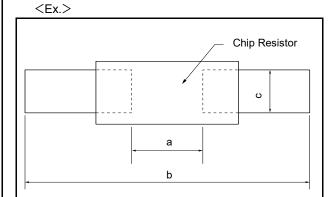
Tape width (W)	Dimensions									
rape widin (vv)	øΑ	øN	øС	W ₁	W ₂					
4 mm width	180.0±3.0			4.5±0.5	7.0±0.5					
8 mm width	180.0 0/-1.5	60.0+1.0/0	13.0±0.2	9.0+1.0/0	11.4±1.0					
12 mm width	100.0 0/-1.5		13.0±0.2	13.0+1.0/0	15.4±1.0					
24 mm width	380.0±2.0	80.0±1.0		25.4±1.0	29.4±1.0					

Unit: mm



Recommended land pattern

• An example of a land pattern for the rectangular type is shown below.



High power (double-sided resistive elements structure) type

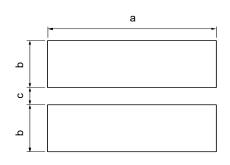
Part No.	Size	[Dimension	S
i ait ivo.	(inch)	а	b	С
ERJ2LW/2BW	1005 (0402)	0.52	1.4 to 1.6	0.4 to 0.6
ERJ3LW/3BW	1608 (0603)	0.5 to 0.8	2.5 to 2.7	0.9 to 1.1
ERJ6LW		0.6 to 0.8	3.2 to 3.8	1.1 to 1.4
ERJ6BW		0.9	3.2 to 3.8	1.1 to 1.4
ERJ6CW (10 to 13 mΩ)	2012 (0805)	0.7 to 0.9	3.2 to 3.8	1.1 to 1.4
ERJ6CW (15 to 30 mΩ)		0.9 to 1.1	3.2 to 3.8	1.1 to 1.4
ERJ8BW				
ERJ8CW (10 to 16 mΩ)	3216 (1206)	1.2	4.4 to 5.0	1.3 to 1.8
ERJ8CW (18 to 50 mΩ)		2.0 to 2.6	4.4 to 5.0	1.2 to 1.8

Unit : mm

Size	Dimensions			
mm/inch	а	b	С	
0402/01005	0.15 to 0.20	0.5 to 0.7	0.20 to 0.25	
0603/0201	0.3 to 0.4	0.8 to 0.9	0.25 to 0.35	
1005/0402	0.5 to 0.6	1.4 to 1.6	0.4 to 0.6	
1608/0603	0.7 to 0.9	2.0 to 2.2	0.8 to 1.0	
2012/0805	1.0 to 1.4	3.2 to 3.8	0.9 to 1.4	
3216/1206	2.0 to 2.4	4.4 to 5.0	1.2 to 1.8	
3225/1210	2.0 to 2.4	4.4 to 5.0	1.8 to 2.8	
4532/1812	3.3 to 3.7	5.7 to 6.5	2.3 to 3.5	
5025/2010	3.6 to 4.0	6.2 to 7.0	1.8 to 2.8	
6432/2512	5.0 to 5.4	7.6 to 8.6	2.3 to 3.5	
6432/2512*	3.6 to 4.0	7.6 to 8.6	2.3 to 3.5	

^{*} ERJL1W

• An example of a land pattern for high power chip resistors / Wide terminal type is shown below.



			Unit : mm		
Part No.	Dimensions				
i ait ivo.	а	b	С		
ERJA1	6.4	1.70	0.60		
ERJB1					
ERJC1*1	5.0	1.30	0.75		
ERJD1*2					
ERJB2	3.2	0.95	0.70		
ERJD2*2	3.2	0.95	0.70		
ERJB3	2.0	0.80	0.60		

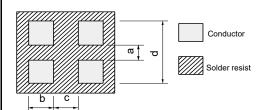
^{*1:} Anti-Sulfurated High power chip resistors / Wide terminal type

^{*2:} Low TCR High power chip resistors / Wide terminal type



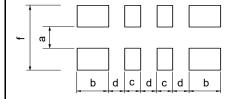
Recommended land pattern

• An example of a land pattern for Chip Resistor Array, Anti-Sulfurated Chip Resistor Array and Chip Attenuator is shown below.



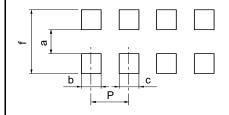
Part No.	Dimensions				
Fait No.	а	b	С	d	
EXB14V EXB14A	0.30	0.30	0.30	0.80 to 0.90	
EXB24V EXBU24 EXB24A	0.5	0.35 to 0.40	0.30	1.4 to 1.5	

Unit : mm

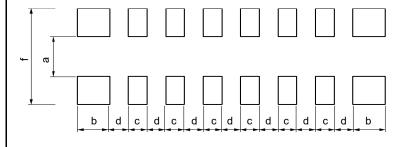


Part No.	Dimensions				
i ait ivo.	а	b	С	d	f
EXB28V EXBU28	0.40	0.525	0.25	0.25	1.40
EXBN8V	0.45 to 0.50	0.35 to 0.38	0.25	0.25	1.40 to 2.00

Unit : mm



David Na	Dimensions				
Part No.	а	b c		f	Р
EXB18V	0.20 to 0.30	0.15 to 0.20	0.15 to 0.20	0.80 to 0.90	0.40
EXBV4V EXBV8V	0.7 to 0.9	0.4 to 0.45	0.4 to 0.45	2 to 2.4	0.80
EXB34V EXB38V EXBU34 EXBU38	0.7 to 0.9	0.4 to 0.5	0.4 to 0.5	2.2 to 2.6	0.80
EXBS8V	1 to 1.2	0.5 to 0.75	0.5 to 0.75	3.2 to 3.8	1.27



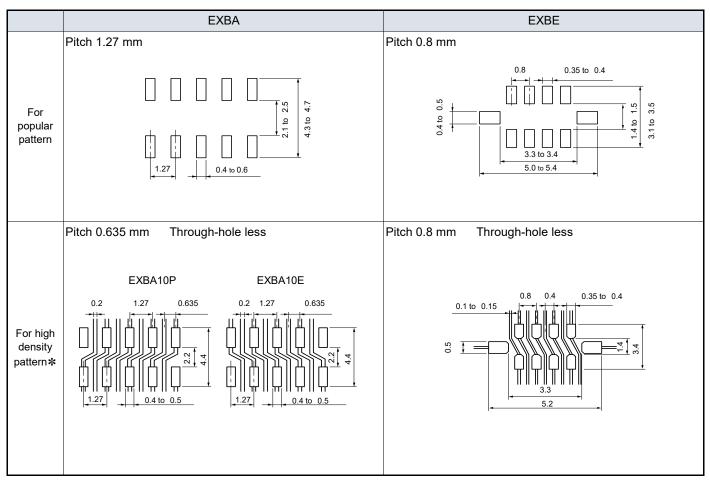
Unit:mm

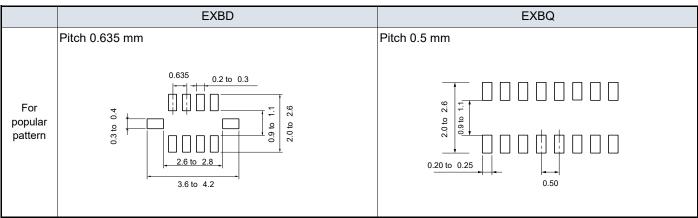
Part No.	Dimensions				
raitino.	а	b	С	d	f
EXB2HV EXBU2H	1.00	0.425	0.25	0.25	2.00



Recommended land pattern

• An example of a land pattern for Chip Resistor Networks is shown below.





* When designing high density land patterns, examine the reliability of isolation among the lines and adopt the chip resistor networks.

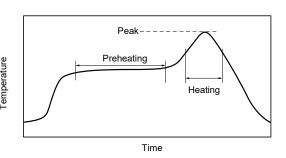


Recommended soldering conditions (Rectagular type)

Recommendations and precautions are described below.

• Recommended soldering conditions for reflow

- Reflow soldering shall be performed a maximum of two times.
- •Please contact us for additional information when used in conditions other than those specified.
- •Please measure the temperature of the terminals and study every kind of solder and printed circuit board for solderability be fore actual use.



For soldering (Example : Sn/Pb)

	· · · · · · · · · · · · · · · · · · ·				
	Temperature	Time			
Preheating	140 ℃ to 160 ℃	60 s to 120 s			
Main heating	Above 200 ℃	30 s to 40 s			
Peak	235 ± 5 ℃	max. 10 s			

For lead-free soldering (Example : Sn/Ag/Cu)

	Temperature	Time
Preheating	150 ℃ to 180 ℃	60 s to 120 s
Main heating	Above 230 ℃	30 s to 40 s
Peak	max. 260 ℃	max. 10 s

Recommended soldering conditions for flow

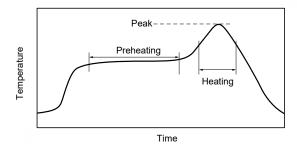
	For soldering		For lead-free soldering	
	Temperature	Time	Temperature	Time
Preheating	140 ℃ to 160 ℃	60 s to 120 s	150 ℃ to 180 ℃	60 s to 120 s
Soldering	245 ± 5 ℃	20 s to 30 s	max. 260 ℃	max. 10 s

Recommended soldering conditions (Chip resistor array / networks and Chip attenuator)

Recommendations and precautions are described below.

Recommended soldering conditions for reflow

- Reflow soldering shall be performed a maximum of two times.
- •Please contact us for additional information when used in conditions other than those specified.
- Please measure the temperature of the terminals and study every kind of solder and printed circuit board for solderability be fore actual use.



For soldering (Example: Sn/Pb)

	Temperature	Time
Preheating	140 ℃ to 160 ℃	60 s to 120 s
Main heating	Above 200 ℃	30 s to 40 s
Peak	235 ± 5 ℃	max. 10 s

For lead-free soldering (Example : Sn/Ag/Cu)

	<u> </u>	0 /
	Temperature	Time
Preheating	150 ℃ to 180 ℃	60 s to 120 s
Main heating	Above 230 ℃	30 s to 40 s
Peak	max. 260 ℃	max. 10 s

Flow soldering

We do not recommend flow soldering, because a solder bridge may form. Please contact us regarding flow sol der ing of EXBA series.



Standard for resistance value and resistance tolerance

Basis standard

IEC Publication 60062 : Marking codes for resistors and capacitors.

IEC Publication 60063 : Preferred number series forresistors and capacitors.

JIS C 5062 : Marking codes for resistors and capacitors.

JIS C 5063 : Preferred number series for resistors and capacitors.

Resistance values

The resistance values are notched by "Ratio" below in each series.

Series	Resistance tolerance (Standard)	Ratio	Remarks
E6	±20 %	6√10=1.46	
E12	±10 %	12√10=1.21	
E24	± 5 %	²⁴ √10=1.10	Please refer to standard resistance values shown on this catalog.
E48	± 2 %	48√10=1.05	<u> </u>
E96	± 1%	96√10=1.02	

How to express the resistance value with a Panasonic part number

The resistance value expressed in ohms is iden tified by a three digit number or a four digit number.

The last digit specifies the number of zeroes to follow.

The letter "R" shall be used as the decimal point for less than 10 Ω .

The examples of a three digit number

···· ortainpios of a times aign manage.				
Resistance code	Value in ohms (Ω)			
R56	0.56			
5R6	5.6			
100	10			
271	270			
102	1 k			
273	27 k			
104	100 k			
275	2.7 M			
106	10 M			
107	100 M			

The examples of a four digit number

Resistance code	Value in ohms (Ω)			
R562	0.562			
5R62	5.62			
56R2	56.2			
1000	100			
2711	2.71 k			
1002	10 k			
2713	271 k			
1004	1 M			
2751	2.71 M			
1006	100 M			

How to express the resistance tolerance with a Panasonic part number

The resistance tolerance is identified by a single letter in accordance with the following table and the code is placed just before the resistance code in the following examples.

Tolerance code	Tolerance (%)	Examples
W	± 0.05	W1001 : 1000 Ω ± 0.05 %
В	± 0.1	B1001 : 1000 Ω ± 0.1 %
С	± 0.25	C1001 : 1000 Ω ± 0.25 %
D	± 0.5	D1001 : 1000 Ω ± 0.5 %
F	± 1	F1001 : 1000 Ω ± 1 %
G	± 2	G1001 : 1000 Ω ± 2 %
J	± 5	J101 : 100 Ω ± 5 %
K	± 10	K101 : 100 Ω ± 10 %
М	± 20	M101 : 100 Ω ± 20 %



Standard resistance values

0.00	uaru		arice	values
E6	E12	E24	E48	E96
	10	10	100	100
				102
			105	105
				107
		11	110	110
				113
				115
			115	118
10			464	121
		12	121	124
			127	127
			127	130
	12		133	133
		12	133	137
		13	140	140
			140	143
			147	147
	15	15		150
			154	154
		16		158
			162	162
				165
			169	169
				174
15			178	178
	18	18	178	182
			187	187
				191
			196	196
		20		200
			205	205
				210

E6	E12	E24	E48	E96
		22	215	215
				221
			226	226
				232
	22		237	237
				243
			040	249
		24	249	255
22			261	261
			201	267
			274	274
		27	214	280
			287	287
	27		201	294
			301	301
		30	301	309
			316	316
			310	324
	33	33	332	332
				340
			348	348
				357
		36	365	365
				374
33		39	383	383
	39			392
			402	402
				412
		43	422	422
				432
			442	442
				453

E6	E12	E24	E48	E96
	47	47	464	464
				475
			487	487
				499
		51	511	511
				523
		51	500	536
47			536	549
47			562	562
		56	302	576
		30	590	590
	56		390	604
	50		619	619
		62	013	634
		02	649	649
			U+3	665
		68	681	681
				698
			715	715
	68			732
		75	750	750
				768
			787	787
68				806
	82	82	825	825
				845
			866	866
				887
		91	909	909
				931
			953	953
				976

Safty Precautions

When using our products, no matter what sort of equipment they might be used for, be sure to confirm the applications and environmental conditions with our specifications in advance.



Panasonic Industry Co., Ltd. Device Solutions Business Division

1006 Kadoma, Kadoma City, Osaka 571-8506 Japan